# MAINTENANCE MANUAL ORION<sup>TM</sup>

# **UHF POWER AMPLIFIER UNITS**

344A4573P1	20 WATT	403-440 MHz
344A4573P2	20 WATT	440-470 MHz
344A4573P3	40 WATT	403-440 MHz
344A4573P4	40 WATT	440-470 MHz
344A4573P5	35 WATT	470-512 MHz
344A4573P6	100 WATT	403-440 MHz
344A4573P7	100 WATT	440-470 MHz
344A4573P8	80 WATT	470-512 MHz

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# DESCRIPTION

The Radio Frequency (**RF**) Power Amplifiers for the UHF **ORION**<sup>TM</sup> mobile radio are provided in three different frequency ranges and power levels designated as follows:

- 344A4573P1 (CAH-545EA) 403-440 MHz, 20 WATT used in low power applications
   344A4573P2 (CAH-545EB) - 440-470 MHz, 20 WATT used in low power applications
- 344A4573P3 (CAH-545LA) 403-440 MHz, 35/40 WATT used in mid power applications 344A4573P4 (CAH-545LB) - 440-470 MHz, 35/40 WATT used in mid power applications 344A4573P5 (CAH-545LC) - 470-512 MHz, 35/40 WATT used in mid power applications
- 344A4573P6 (CAH-545HA) 403-440 MHz, 80/100 WATT used in high power applications 344A4573P7 (CAH-545HB) - 440-470 MHz, 80/100 WATT used in high power applications 344A4573P8 (CAH-545HC) - 470-512 MHz, 80/100 WATT used in high power applications

The exciter for each of the three power amplifiers is located on Synthesizer/Receiver/Exciter board CMN-354-1. This exciter circuit provides approximately 500 milliwatt input to the PA (refer to Maintenance Manual LBI- 38905). The PA utilizes a single power amplifier module (HC1) as the driver unit. In the case of the 20 watt amplifier the power module is the only power amplifying unit (Refer to Figure 1). With the other two power levels the power module drives other power transistors to provide the power output required (Refer to Figures 2 and 3). Each power amplifier is provided with an antenna switch and limiter circuit to isolate the receive circuit from the transmit circuit, limiting the receiver input from being over driven due to large RF signals. Each power amplifier has a power detect circuit which controls an Automatic Power Control (APC) circuit to keep the power output constant. A low-pass filter is provided in the antenna circuit to reduce harmonic emissions. A keyed Tx 9V regulator is provided to power the APC circuits.

# **CIRCUIT ANALYSIS**

### 20 WATT

The 20 Watt PA assembly uses one power module (HC1) to provide the output power.

Supply voltage for the power amplifier is connected from power leads on the System Interface Board to J3 (A+) and G (A-) on the PA Board. Diode CD7 is a surge protector to suppress pulses on the power leads. Diode CD8 will cause the fuse to blow if the polarity of the power leads is reversed.

The Exciter output is coupled through connector J151 on the Synthesizer/Receiver/Exciter Board to input connector J1 on the PA board. The 500 milliwatt RF input at J1 is coupled to power module HC1 through an attenuator pad consisting of resistors R1-R3. This pad attenuates the power to about 300 milliwatt and provides isolation between Exciter and PA. The power module (HC1) amplifies the 300 milliwatt input to 20 Watts.

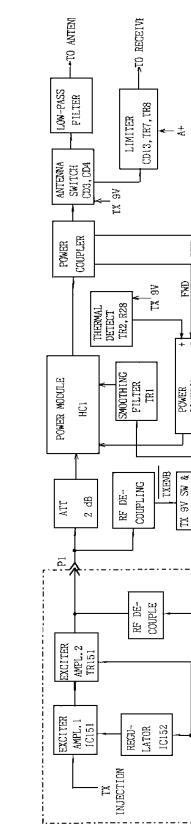
The power module consists of a three-stage RF amplifier (Refer to **IC DATA**). The first stage power supply voltage is supplied by the power control circuit. The second and third stage power supply voltage is supplied by **SMOOTHING FILTER** transistor TR1. The second and third stage RF amplifiers operate as class C.

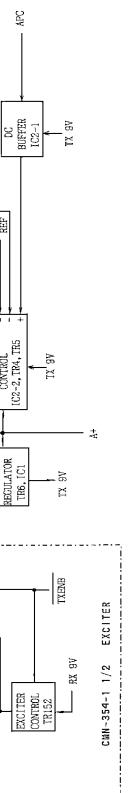
The 20 Watts output of HC1 is coupled to the **ANTENNA** and **ANTENNA SWITCH & LIMITER** circuits through 50 ohm stripline Z1.

# Antenna Switch & Limiter

The Antenna Switch circuit consists of capacitor C25 and inductor L9 and takes the place of a quarter-wave micro strip line. When **TX9V** output goes high, bias current flows through switching diodes CD3 and CD4. A low impedance now exists at the anode of CD4 and a high impedance exists at the node connection of C25 and L9. This isolates the transmitter power from the receiver. Diode CD3 is now an RF short and along with capacitor C12, couples the power to the lowpass filter and on to the antenna.

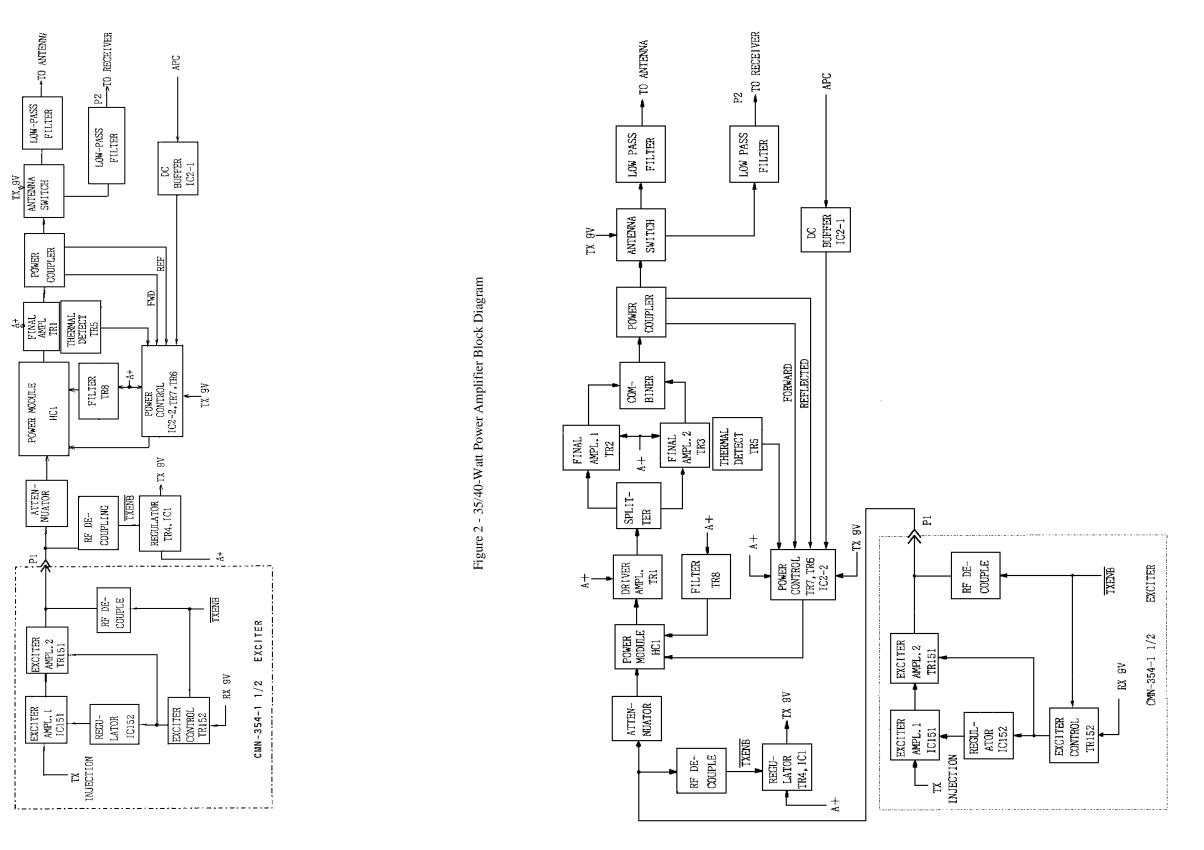
The limiter circuit consists of transistors TR7, TR8 and diode package CD13. While receiving, if the received signal level exceeds +10 dBm, the rectified currents of CD13 provide forward bias to TR7, TR8 and PIN diode CD4 proportional to the received signal level. This causes a quarter-wave circuit (lumped constants C25 and L9) to turn on when the received signal exceeds +10 dBm and protects the receiver from excessively high receive signal levels.





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Figure 1 - 20-Watt Power Amplifier Block Diagram



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Figure 3 - 80/100 - Watt Power Amplifier Block Diagram

# **Tx 9V Switch**

When the lead, located on the Synthesizer/Receiver/Exciter board, goes low, the DC voltage on J151 goes low. On the PA board, the DC voltage on J1 also goes low completing the circuit for diode CD9. With CD9 conducting TX 9V Switch transistor TR6 conducts applying A+(13.32 V) to the input of +9 Volt Regulator IC1. The regulated +9 volts applies bias to operational amplifier IC2, transistor TR2 and switching diodes CD3 and CD4.

### **Power Control**

The Auto Power Control (APC) circuit protects the transmitter PA from damage due to:

a. excessive output power

b. excessive reflected power

or

c. excessive temperature
--------------------------

The output power control circuit allows the RF output power to be set at rated power by the APC voltage from the Logic/IF/Audio Board. If the output power of the PA increases, the detected voltage and the input to operational amplifier IC2-2 increases. The output voltage of operational amplifier IC2-2 decreases. This causes **DC DRIVER** transistor TR5 to conduct less. This increases the base voltage on PNP DC PASS transistor TR4, causing it to conduct less. This results in less voltage being applied to the first amplifier stage in RF Power Module HC1, reducing the output power of the PA in proportion to the increases in output power detected by the circuit.

To protect the PA against badly mismatched loads, a reverse power detector circuit (VSWR) consisting of diode CD2, transistor TR5, operational amplifier IC2-2 and pass transistor TR4 detects reverse (reflected) power. When sufficient power is detected by CD2 to cause it to conduct, the voltage at the output of IC2-2 decreases, causing the Power Module to lower the output power, protecting the PA. The reverse power level is set by resistor R8 connected in series with diode CD2.

The PA is protected against temperature increases by a thermal detector circuit. This circuit consists of resistor R28, THERMAL DETECT transistor TR2, DC DRIVER transistor TR5 and DC AMPL operational amplifier IC2-2. As temperature increases, the resistance to ground through thermal detector resistor R28 increases. This causes IC2-2 to conduct less, causing a decrease in PA output until the temperature level is reduced. The temperature level is set by resistor R28. When the heatsink temperature rises above 90 C, the resistance of R28 increases and the power output is reduced.

# 35/40 WATT

The 35/40 Watt PA assembly uses one power module (HC1) and one RF power transistor (TR1) to provide the output power.

Supply voltage for the power amplifier is connected from power leads on the System Interface Board to J3 (A+) and G (A-) on the PA Board. Diode CD2 is a surge protector to suppress pulses on the power leads. (Diode CD1001 in the PA UNIT will cause a fuse to blow if the voltage polarity is reversed. Refer to the PA INTERCONNECTION DIAGRAM)

Test Points (TP) are the printed board terminals for measuring control voltage as follows:

- TP1 A+ (13.42V)
- TP2 Control Voltage (4.72V)
- TP3 Forward Power Detect (2.64V)
- TP4 Tx 9V (9.12V)
- TP5 APC Voltage on output of DC AMPL IC2-1 (2.64V)
- TP6 Voltage to HC1, pins 3 &4 (12.5V)
- TP7 APC Voltage (3.5V)

The Exciter output is coupled through connector J151 on the Synthesizer/Receiver/Exciter Board to input Jack P1 on the PA board. The 500 milliwatt RF input at P1 is coupled to power module HC1 through an attenuator pad consisting of resistors R1-R4. This pad attenuates the 500 milliwatt to about 300 milliwatt and provides isolation between Exciter and PA. The power module (HC1) amplifies the 300 milliwatt input to 13 Watts.

The power module consists of a three-stage RF amplifier (Refer to IC DATA). The first stage power supply voltage is supplied by the power control circuit. The second and third stage power supply voltage is supplied by SMOOTHING FILTER transistor TR8. The second and third RF amplifiers operate as class C.

The 13 Watts output of HC1 is coupled to **POWER AMPL** transistor TR1 through impedance matching components consisting of capacitors C7, C9, C10 and inductor L2 through coupling capacitor C8. Transistor TR1 amplifies the 13 Watt level to 40 Watts. The output of TR1 is coupled to the ANTENNA and ANTENNA SWITCH through impedance matching components consisting of capacitors C11-C13, inductor L6 and impedance matching network Z2 through coupling capacitor C14 and 50 ohm stripline Z7.

# Antenna Switch

The Antenna Switch circuit consists of capacitor C64 and inductor L23 and takes the place of a quarter-wave micro strip line. When **TX9V** output goes high, bias current flows through switching diodes CD5, CD7 and CD9. A low impedance now exists at the anode of CD7 and a high impedance exists at the connection of C64 and L23. This isolates the transmitter power from the receiver. Diode CD5 is now an RF short and along with capacitor C55 couples the power to the lowpass filter and on to the antenna.

# **Tx 9V Switch**

When the **TX ENB** lead goes low, TX 9V switch transistor TR4 conducts applying A+ (13.32 V) to the input of +9 Volt Regulator IC1. The regulated +9 volts (TX 9V) applies bias to operational amplifier IC2, transistor TR5 and switching diodes CD5, CD7 and CD9.

# **Power Control**

The Auto Power Control (APC) circuit protects the transmitter PA from damage due to:	
a. excessive output power	
b. excessive reflected power	
or	
c. excessive temperature	

The output power control circuit allows the RF output power to be set at rated power by the APC voltage from the Logic/IF/Audio Board. If the output power of the PA increases, the detected voltage and the input of operational amplifier IC2-2 increases. The output voltage of IC2-2 decreases. This causes DC DRIVER transistor TR6 to conduct less. This increases the base voltage on PNP DC PASS transistor TR7, causing it to conduct less. This results in less voltage being applied to the first amplifier stage in driver module (HC1), reducing the output power of the PA in proportion to the increases in output power detected by the circuit.

To protect the PA against badly mismatched loads, a reverse power detector circuit (VSWR) consisting of diode CD4, transistor TR6, operational amplifier IC2-2 and pass transistor TR7 detects reverse (reflected) power. When sufficient power is detected by CD4 to cause it to conduct, the voltage at the output of IC2-2 decreases, causing the driver module to lower the output power, protecting the PA. The re-

The PA is protected against temperature increases by a thermal detector circuit. This circuit consists of resistor R49. transistors TR5, TR6, TR7 and operational amplifier IC2-2. As temperature increases, the resistance to ground through thermal detector resistor R49 increases. This causes IC2-2 to conduct less, causing a decrease in PA output until the temperature level is reduced. The temperature level is set by resistor R49. When the heatsink temperature rises above 90 C, the resistance of R49 increases and the power output is reduced.

verse power level is set by resistor R15 connected in series with diode CD4.

# 80/100 WATT

The 80/100 Watt PA assembly uses one power module (HC1) and three RF power transistors (TR1, TR2 and TR3) to provide the output power.

Supply voltage for the power amplifier is connected from power leads on the System Interface Board to J3 (A+) and G (A-) on the PA Board. Capacitors C73 and C95 prevent RF from getting on the power leads. Diode CD1 causes a fuse to blow if the polarity of the power leads is reversed. Diode CD2 is a surge protector to suppress pulses on the power leads.

Test Points (TP) are the printed board terminals for measuring control voltage as follows:

- TP1 A+ (13.32V)
- TP2 Control Voltage (4.27V)
- TP3 Forward Power Detect (3.2V)
- TP4 Tx 9V (9.2V)
- TP5 APC Voltage on output of DC AMPL IC2-1 (2.66V)
- TP6 Voltage to HC1, pins 3 &4 (12.8V)
- TP7 APC Voltage (3.5V)

The exciter output is coupled through connector J102 on the Synthesizer/Receiver/Exciter Board to input Jack P1 on the PA board. The 500 milliwatt RF input at P1 is coupled to power module HC1 through an attenuator pad consisting of resistors R1 through R4. This pad attenuates the 500 milliwatt input to 300 milliwatt and provides isolation between the Exciter and PA. POWER MODULE HC1 amplifies the 300 milliwatt input to 12 Watts. The power module (HC1) consists of a three stage RF amplifier. The first stage of the module is controlled by the voltage from the power control circuit. The amplifier consist of a Class C driver amplifier and two Class C common-emitter amplifiers. The 12 watt

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# 403-512 MHz. 20-WATT POWER MODULE HC1

403-512 MHz. 35/40 -WATT POWER MODULE HC1

output is coupled to DRIVER AMPL transistor TR1 through impedance matching components consisting of capacitors C7, C9 C10, inductors L2 through L4 and coupling capacitor C8. The output of TR1 is coupled to the power **SPLITTER** through the impedance matching components consisting of capacitors C11 through C13, C15, C96, C97, inductor L6 and impedance matching network Z1 through coupling capacitor C14. Transistor TR1 amplifies the 12 watt input level to 40 watts. The power splitter consists of capacitors C18, C27, C36 and Inductors L7 and L11. Resistor R5 absorbs any unbalance in the drive to POWER AMPL-1. AMPL-2 transistors TR2 and TR3. These power amplifier stages consist of two identical paralleled Class C power amplifiers. The output of the power splitter is coupled to transistors TR2 and TR3 through coupling capacitors C19 and C28 and the impedance matching components consisting of capacitors C20, C21, C29 and C30. The output of TR2 and TR3 is coupled to the power combiner through impedance matching components consisting of capacitors C22-C25, C31-C34 and impedance matching networks Z2 and Z3. The power **COMBINER** consists of capacitors C26, C35, C40, C41 and inductors L10, L14 and L15, Resistor R8 absorbs the difference in the output power of TR2 and TR3. Transistors TR2 and TR3 each amplify the input level from 20 watts to about one-half (1/2) of the rated output power. The output of the combiner is coupled to the ANTENNA **SWITCH** through 50 ohm stripline Z7.

### Antenna Switch

The antenna switch circuit consists of capacitor C64 and inductor L23 and takes the place of a quarter-wave micro strip line. When **TX9V** output goes high, bias current flows through switching diodes CD6 through CD9. A low impedance now exists at the anode of CD7 and CD8 and high impedance exists at the connection of C64 and L23. This isolates the transmitter power from the receiver. Diode CD6 is now an RF short and along with capacitor C55 couples the power to the lowpass filter and on to the antenna.

# Tx 9V Switch

When the **TX ENB** lead goes low, **TX 9V** switch transistor TR4 conducts applying A+ (13.32 V) to the input of +9 Volt Regulator IC1. The regulated +9 volts (TX 9V) applies bias to operational amplifier IC2, transistor TR5 and switching diodes CD6 through CD9.

# **Power Control**

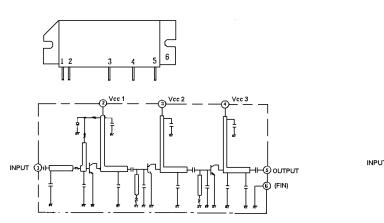
The Automatic Power Control (APC) circuit protects the transmitter PA from damage due to:

- a. excessive output power
- b. excessive reflected power
- or
- c. excessive temperature

The output power control circuit allows the RF output power to be set at rated power by the APC voltage from the LOGIC/IF/AUDIO Board. If the output power of the PA increases, the detected voltage and the input of operational amplifier IC2-2 increases. The output voltage of operational amplifier IC2-2 decreases. This causes transistor TR6 to conduct less. This increases the base voltage on PNP pass transistor TR7, causing it to conduct less. This results in less voltage being applied to the first amplifier stage in driver module (HC1), reducing the output power of the exciter/ PA in proportion to the increases in output power detected by the circuit.

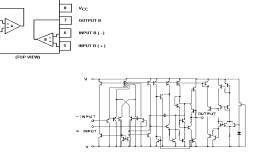
To protect the PA against badly mismatched loads, a reverse power detector circuit (VSWR) consisting of diode CD4, transistor TR6, operational amplifier IC2-2 and pass transistor TR7 detect reverse (reflected) power. When sufficient power is detected by CD4 to cause it to conduct, the voltage at the output of IC2-2 decreases, causing the driver module to lower the output power, protecting the PA. The reverse power level is set by resistor R15 connected in series with diode CD4.

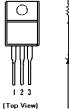
The PA is protected against temperature increases by a thermal detector circuit. This circuit consists of resistor R49, transistors TR5, TR6, TR7 and operational amplifier IC2-2. As temperature increases, the resistance to ground through thermal detector resistor R49 increases. This causes IC2-2 to conduct less, causing a decrease in PA output until the temperature level is reduced. The temperature level is set by resistor R49. When the heatsink temperature rises above 90 C, the resistance of R49 increases and the power output is reduced.

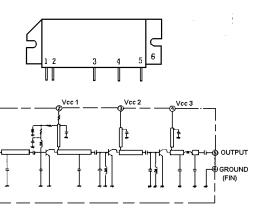


### **9 VOLT REGULATOR IC1**

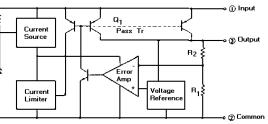








# **OPERATIONAL AMPLIFIER IC2**



# PA UNIT (EUROPEAN MODEL) 344A4573P1/JHM-471EA, 344A4573P2/JHM-471PEB

SYMBOL	PART NO.	DESCRIPTION
A1	NOTE: Parts listed are for reference	PA CIRCUIT CAH-545EA (Used in 344A4573P1).
A1	only. Refer to Service Section for	PA CIRCUIT CAH-545EB (Used in 344A4573P2).
A2	serviceable parts.	INTERFACE CMH-1231E.
		CAPACITORS
C1001 and C1002		Ceramic: 1000 pF +50%, -20% 50 VDCW temp coef ±15%.
		CONNECTORS
J1001		H-6JALD00005.
TB1001		2 ALB-01A.
W1001		WIRE 250V-HV-19/0.18-(2)
		COAXIAL CABLES
ZC1002		H-6JJLD17125A.
ZC1003		H-6JJLD17090A.
ZC1004		H-6ZCLD41060.

### PA UNIT (USA MODEL)

344A573P3/JHM-471PLA 344A573P4/JHM-471PLB

344A4573P5/JHM-471PLC 344A4573P6/JHM-471PHA 344A4573P7/JHM-471PHB 344A4573P8/JHM-471PHC

SYMBOL	PART NO.	DESCRIPTION
A1001	NOTE: Parts listed are for reference	PA CIRCUIT CAH-545LA (Used in 344A4573P3).
A1001	only. Refer to Service Section for	CIRCUIT CAH-545LB (Used in 344A4573P4).
A1001	serviceable parts.	PA CIRCUIT CAH-545LC (Used in 344A4573P5).
A1001		PA CIRCUIT CAH-545HA (Used in 344A4573P6).
A1001		PA CIRCUIT CAH-545HB (Used in 344A4573P7).
A1001		PA CIRCUIT CAH-545HC (Used in 344A4573P8).
A1002		INTERFACE (Used in 344A4573P3,P4,P5).
A1002		INTERFACE (Used in 344A4573P6,P7,P8).
		CAPACITORS
C1001		Ceramic: 1000 pF +200%,-0%, 50 VDCW temp coef +20%,-55%.
C1002		Ceramic: 1000 pF +200%,-0%, 50 VDCW temp coef +20%,-55% ( Used in P6,P7,P8).
C1004		Ceramic: 1000pF +50-20% 50 VDCW.
		DIODE
CD1001		Silicon fwd current 3A, 200 PIV ;sim to MOTOROLA MR751 (Used in 344A4573P3,P4,P5).
		JACKS
J1001		Connector: TNC-R888.

SYMBOL	PART NO.	DESCRIPTION
J1002		CCT9402-0501R.
J1004		2-171822-4.
J1004-1 thru J1004-4		170204-4.
		WIRES
W1001		250V-HV-19/0.18-(1).
W1002		250V-HV-19/0.18-(9).
W1003		250V-HV-19/0.18-(2).
W1004		250V-HV-19/0.18-(0).

ZC1002

ZC1003

ZC1003

# ----COAXIAL CABLES----H-6ZCLD41060. H-6ZCLD40111 (Used in 344A4573P6,P7,P8). H-6ZCLD40009 (Used in 344A4573P3,P4,P5). POWER AMPLIFIER CAH-545E - 20 WATT CAH-545EA (Used in 344A4573P1) CAH-545EB (Used in 344A4573P2)

SYMBOL	PART NO.	DESCRIPTION
		CAPACITORS
C1 and C2	NOTE: Parts listed are for reference only. Refer to	Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM.
C3	Service Section for serviceable parts.	Electrolytic: 33 $\mu F$ ±20% 25 VDCW, temp coef ±20%.
C4		Film: 0.1 $\mu F$ ±10% 50 VDCW, temp coef ±15%.
C5		Ceramic: 4.7 pF $\pm$ 10% 50 VDCW, temp coef $\pm$ 10%.
C7		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM.
C8		Ceramic: 7 pF $\pm$ 0.5pF 50 VDCW, temp coef 0 $\pm$ 30PPM. (Used in EA).
C8		Ceramic: 6 pF $\pm$ 0.5pF 50 VDCW, temp coef 0 $\pm$ 30PPM. (Used in EB).
C11		Ceramic: 7 pF ±0.5pF 50 VDCW, temp coef 0±30PPM. (Used in EA).
C11		Ceramic: 6 pF ±0.5pF 50 VDCW, temp coef 0±30PPM. (Used in EB).
C12		Ceramic: 100 pF ±5% 500 VDCW, temp coef 0±60 PPM.
C13 and C14		Ceramic: 3 pF $\pm$ 0.25pF 500 VDCW, temp coef 0 $\pm$ 120 PPM.
C15		Ceramic: 2 pF ±0.25 PF 500 VDCW, temp coef 0±250 PPM.
C16		Ceramic: 3 pF ±0.25pF 500 VDCW, temp coef 0±120 PPM.
C17		Ceramic: 5 pF ±0.25pF 500 VDCW, temp coef 0±60 PPM.
C19		Ceramic: 6 pF ±0.5pF 500 VDCW, temp coef 0±60PPM.
C20		Ceramic: 2 pF ±0.25 PF 500 VDCW, temp coef 0±250 PPM.
C21		Electrolytic: 220 $\mu\text{F}$ ±20% 25 VDCW, temp coef ±20%.

# PARTS LIST

SYMBOL	PART NO.	DESCRIPTION
C22		Ceramic: 100 pF ±5% 50 VDCW, temp
thru		coef 0±30 PPM.
C24		
C25		Ceramic: 4 pF ±0.25 pF 500 VDCW, temp coef 0±60 PPM.
C26		Ceramic: 4 pF ±0.25 pF 50 VDCW, temp coef 0±30 PPM.
C27		Ceramic: 2 pF ±0.25 pF 50 VDCW, temp coef 0±30 PPM.
C28		Ceramic: 100 pF $\pm$ 5% 50 VDCW, temp coef 0 $\pm$ 30 PPM.
C30		Tantalum: 4.7 μF ±20% 25 VDCW.
C31		Electrolytic: $10 \ \mu\text{F} \pm 20\% 25 \ \text{VDCW}$ , temp coef $\pm 20\%$ .
C32		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30PPM.
C34		Electrolytic: 10 $\mu$ F ±20% 25 VDCW, temp coef ±20%.
C35		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM.
C36		Tantalum: 1 uF $\pm 20\%$ 16 VDCW.
C37		Ceramic: 100 pF $\pm$ 5% 50 VDCW, temp coef 0 $\pm$ 30 PPM.
C38		Ceramic: 0.1 μF +80%,-20% 25 VDCW, temp coef +30%,-80%.
C39		Ceramic: 100 pF ±5% 50 VDCW, temp
and		coef $0\pm30$ PPM.
C40		
C43		Ceramic: 6 pF ±0.5 pF 500 VDCW, temp coef 0±60 PPM.
C44		Ceramic: 4 pF $\pm$ 0.25 pF% 50 VDCW, temp coef 0 $\pm$ 30PPM.
C60 thru C62		Ceramic: 100 pF $\pm$ 5% 500 VDCW, temp coef 0 $\pm$ 60PPM.
		DIODES
CD1 and		Silicon: sim to PANASONIC MA741-TX.
CD2		
CD3		PIN DIODE: sim to NIHONMEICOM H-
and CD4		6txld00001.
CD4 CD7		VARISTOR: sim to PANASONIC ERZ-
CD8		CF2MK220. Silicon: sim to MOTOROLA MR751.
CD9		Silicon: fast recovery (2 diodes in cathode common): sim to TOSHIBA ISS184
CD13		Silicon: fast recovery : sim to TOSHIBA ISS226.
		INTEGRATED CIRCUITS
HC1		RF Power Amplifier: sim to MITSUBISHI M57788L-38 (Used in EA).
HC1		RF Power Amplifier: sim to MITSUBISHI M57788H-38 (Used in
IC1		EB). Linear: Positive Voltage Regulator; sim
IC2		to PANASONIC AN6541. Linear: Dual OP Amp: sim to NEW JRC.
		CONNECTORS
J1		Connector.
and J2		
J3		Connector.
J4	B19/5JTCD00197	Connector.
<u>,</u>	2.0,0010000101	

\*COMPONENTS, ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

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LBI-39034
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SYMBOL	PART NO.	DESCRIPTION
		INDUCTORS
L1		Coil: 0.22 μΗ.
L2		Coil: RF 0.22 μH.
L3 and L4		Coil: 19 nH.
L5 thru L8		RF Coil: AIRWOUND.
L9 and L10		Coil: RF 19 nH.
L10 L11		Coil: RF 0.22 μH.
		RESISTORS
R1		Metal film: 470 ohms ±5%, 100 VDCW, 1/10W.
R2		Metal film: 12 ohms ±5%, 200 VDCW, 1/4W.
R3		Metal film: 470 ohms ±5%, 100 VDCW, 1/10W.
R4 and R5		Metal film: 22 ohms ±5%, 200 VDCW, 1/2W.
R6		Metal film: 100 ohms±5%, 250 VDCW, 1W.
R8		Metal film: 100 ohms±5%, 100 VDCW, 1/10W.
R9 and R10		Metal film: 47 ohms ±5%, 100 VDCW, 1/10W.
R11		Metal film: 47K ohms ±5%, 200 VDCW, 1/8W.
R14		Metal film: 27K ohms ±5%, 100 VDCW, 1/10W.
R15		Metal film: 2.7K ohms ±5%, 100 VDCW, 1/10W.
R16		Metal film: 390 ohms ±5%, 200 VDCW, 1/4W.
R17		Metal film: 470 ohms ±5%, 200 VDCW, 1/4W.
R18		Metal film: 1K ohms ±5%, 100 VDCW, 1/10W.
R19 thru R21		Metal film: 2.2K ohms ±5%, 200 VDCW, 1/10W.
R22		Metal film: 100k ohms ±5%, 100 VDCW, 1/10W.
R23		Metal film: 3.3K ohms ±5%, 100 VDCW, 1/10W.
R24		Metal film: 4.7k ohms ±5%, 100 VDCW, 1/10W.
R25		Metal film: 2.2K ohms ±5%, 100 VDCW, 1/10W.
R26		Metal film: 47K ohms ±5%, 100 VDCW, 1/10W.
R27		Metal film: 1K ohms ±5%, 100 VDCW, 1/10W.
R28		Posistor: sim to MURATA PTH9M04BE222TS2F333.
R35		Metal film: 100 ohms ±5%, 250 VDCW, 1W.
R36		Metal film: 10K ohms ±5%, 100 VDCW, 1/10W.
RV1		Variable: 10K ohms.

(Continued)

# LBI-39034

SYMBOL	PART NO.	DESCRIPTION
		TRANSISTORS
TR1		Silicon, NPN: sim to PANASONIC 2SD1445A.
TR2		Silicon, NPN: sim to NEC 2SD596-T1B DV3.
TR4		Silicon, PNP: sim to PANASONIC 2SB953A.
TR5		Silicon, NPN: sim to NEC 2SD596-T1B DV3.
TR6		Silicon, PNP: sim to NEC 2SB624-T1B BV3.
TR7		Silicon, NPN: sim to NEC 2SD596-T1B DV3.
TR8		Silicon, PNP: sim to NEC 2SB624-T1B BV3.

UHF POWER AMPLIFIER CAH-545L - 35/40 WATT CAH-545H - 80/100 WATT CAH-545LA (Used in 344A4573P3), CAH-545LB (Used in 344A4573P4) CAH-545LC (Used in 344A4573P5), CAH-545HA (Used in 344A4573P6) CAH-545HB (Used in 344A4573P7), CAN-545HC (Used in 344A4573P8)

SYMBOL	PART NO.	DESCRIPTION
		CAPACITORS
C1 and C2	NOTE: Parts listed are for reference only. Refer to	Ceramic: 100 pF $\pm$ 5% 50 VDCW, temp coef 0 $\pm$ 30 PPM.
C3	Service Section for serviceable parts.	Electrolytic: 33 $\mu F$ ±20% 25 VDCW, temp coef ±20%.
C5		Ceramic: 0.01 $\mu F$ ±10% 50 VDCW, temp coef 0±10%.
C6		Ceramic: 0.1 μF +80%,-20% 50 VDCW, temp coef +30%,-80%.
C7		Ceramic: 12 pF $\pm$ 5% 500 VDCW, temp coef 0 $\pm$ 60PPM (Used in LA,LB,HA,).
C7		Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in LC,HB,HC).
C8		Ceramic: 100 pF ±5% 500 VDCW, temp coef 0±60PPM.
C9		Ceramic: 56 pF $\pm$ 5% 500 VDCW, temp coef 0 $\pm$ 60PPM (Used in LA, HA).
C9		Ceramic: 47 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in LB,LC,HB,HC).
C10		Ceramic: 56 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in LA,HA).
C10		Ceramic: 43 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in HB).
C10		Ceramic: 36 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in LC,HC).
C10		Ceramic: 47 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in LB).
C11		Metal mica: 43 pF $\pm$ 5% 100 VDCW, (Used in LA, HA).
C11		Metal mica: 36 pF $\pm$ 5% 100 VDCW, (Used in HB).
C11		Metal mica: 33 pF ±5% 100 VDCW, (Used in LB,HC).
C11		Metal mica: 39 pF $\pm$ 5% 100 VDCW, (Used in LC).
C12		Metal mica: 47 pF $\pm$ 5% 100 VDCW, (Used in LA).
C12		Metal mica: 43 pF ±5% 100 VDCW, (Used in HA,HB).

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# PARTS LIST

C29       Mica: 39 pF ±5% 500 VDCW (Used in HB).       C51         C30       Mica: 36 pF ±5% 500 VDCW (Used in HA).       C52         C30       Mica: 36 pF ±5% 500 VDCW (Used in HA).       C53         C31       Metal mica: 33 pF ±5% 500 VDCW (Used in HA).       C54         C31       Metal mica: 33 pF ±5% 100 VDCW (Used in HC).       C54         C31       Metal mica: 33 pF ±5% 100 VDCW (Used in HC).       C56         C32       Metal mica: 33 pF ±5% 100 VDCW (Used in HB).       C56         C33       Metal mica: 30 pF ±5% 100 VDCW (Used in HB).       C57         C33       Metal mica: 20 pF ±5% 100 VDCW (Used in HB).       C57         C33       Metal mica: 21 pF ±5% 100 VDCW (Used in HA).       C57         C33       Metal mica: 24 pF ±5% 100 VDCW (Used in C57       C57         C34       Mica: 90 pF ±0.5pF 500 VDCW (Used in C57       C57         C35       Ceramic: 0.7 ±0.5pF 500 VDCW, temp coef       C59         C36       Ceramic: 0.7 ±0.5pF 500 VDCW, temp coef       C59         C36       Ceramic: 0.7 ±0.5pF 500 VDCW, temp coef       C59         C36       Ceramic: 0.7 ±0.5pF 500 VDCW, temp coef       C59         C37       Electrolytic: 21 pF ±0.5pF 500 VDCW, temp coef       C59	SYMBOL	PART NO.	DESCRIPTION	SYMBOL	
C30       Mica: 56 pF ±5% 500 VDCW (Used in HA).       C52         C30       Mica: 47 pF ±5% 500 VDCW (Used in HB).       C53         C31       Metal mica: 43 pF ±5% 100 VDCW (Used in HC).       C54         C31       Metal mica: 33 pF ±5% 100 VDCW (Used in HC).       C56         C32       Metal mica: 33 pF ±5% 100 VDCW (Used in HC).       C56         C32       Metal mica: 30 pF ±5% 100 VDCW (Used in HA).       C56         C33       Metal mica: 30 pF ±5% 100 VDCW (Used in HA).       C57         C33       Metal mica: 27 pF ±5% 100 VDCW (Used in HA).       C57         C33       Metal mica: 24 pF ±5% 100 VDCW (Used in HA).       C57         C33       Metal mica: 27 pF ±5% 100 VDCW (Used in HA).       C57         C34       Mica: 9 pF ±0.5 pF 500 VDCW, temp coef cos9       C58         C35       Ceramic: 10 pF ±0.5 pF 500 VDCW, temp coef cos9       C59         C36       Ceramic: 10 pF ±0.5 pF 500 VDCW, temp coef cos9       C59         C36       Ceramic: 10 pF ±0.5 pF 500 VDCW, temp coef cos9       C59         C36       Ceramic: 10 pF ±0.5 pF 500 VDCW, temp coef cos9       C59         C37       Electrolytic: 22 µF ±10% 50 VDCW, temp coef cos9       C60         C600 PPM (Used in HA,HB,HC).       C60 </td <td>C29</td> <td></td> <td>Mica: 39 pF <math>\pm</math>5% 500 VDCW (Used in HB).</td> <td>C51</td> <td></td>	C29		Mica: 39 pF $\pm$ 5% 500 VDCW (Used in HB).	C51	
C30       MIC:: 35 pF 13% 500 VDCW (Used in H4).       C53         C30       Mic:: 36 pF 15% 500 VDCW (Used in H4).       C53         C31       Metal mic:: 33 pF 15% 500 VDCW (Used in H4).       C54         C31       Metal mic:: 33 pF 15% 100 VDCW (Used in H4).       C55         C32       Metal mic:: 33 pF 15% 100 VDCW (Used in H6).       C56         C32       Metal mic:: 36 pF 15% 100 VDCW (Used in H5).       C56         C33       Metal mic:: 36 pF 15% 100 VDCW (Used in H4).       C57         C33       Metal mic:: 30 pF 15% 100 VDCW (Used in H4).       C57         C33       Metal mic:: 24 pF 15% 100 VDCW (Used in C57       C57         C33       Metal mic:: 24 pF 15% 100 VDCW (Used in C57       C58         C33       Metal mic:: 24 pF 15% 100 VDCW (Used in C57       C58         C34       Mic:: 90 pF 15% 500 VDCW (Used in HA,H8).       C58         C35       Ceramic: 10 pF 15% 500 VDCW (temp cef       C59         C36       Ceramic: 10 pF 15% 500 VDCW, temp cef       C59         C37       Electrolytic: 22 µF 110% 40 VDCW (Used in H4).       C59         C38       Ceramic: 10 pF 15% 500 VDCW, temp cef       C60         C41       Mic:: 8 pF 10.5 pF 500 VDCW, temp cef       C60 </td <td>C29</td> <td></td> <td>Mica: 36 pF <math>\pm</math>5% 500 VDCW (Used in HC).</td> <td>050</td> <td></td>	C29		Mica: 36 pF $\pm$ 5% 500 VDCW (Used in HC).	050	
C30       Mica: 36 pF ±5% 500 VDCW (Used in HG).       C33         C31       Metal mica: 33 pF ±5% 100 VDCW (Used in HA, HB).       C54         C31       Metal mica: 33 pF ±5% 100 VDCW (Used in HA).       C55         C32       Metal mica: 36 pF ±5% 100 VDCW (Used in HA).       C56         C33       Metal mica: 30 pF ±5% 100 VDCW (Used in HA).       C57         C33       Metal mica: 21 pF ±5% 100 VDCW (Used in HA).       C57         C33       Metal mica: 22 pF ±5% 100 VDCW (Used in HA).       C57         C33       Metal mica: 24 pF ±5% 100 VDCW (Used in HA).       C57         C34       Mica: 90 pF ±5% 500 VDCW (Used in HA).       C58         C35       Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef coef 0:60PPM. (Used in HA, HB).       C58         C36       Ceramic: 5 pF ±0.5pF 500 VDCW, temp coef 0:60PPM. (Used in HA, HB, HC).       C59         C37       Electrolytic: 22 µF ±10% 40 VDCW, temp coef 0:60PPM. (Used in HA, HB, HC).       C59         C38       Ceramic: 0.1 µF ±0.5pF 500 VDCW, temp coef 0:60PPM. (Used in HA, HB, HC).       C59         C44       Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef 0:60PPM. (Used in HA, HB, HC).       C60         C41       Mica: 6 pF ±0.5pF 500 VDCW, temp coef 0:60PPM. (Used in HA, HB, HC).       C61         C44       <				652	
C31       Metal mica: $43 \text{ pF} \pm 5\%$ 100 VDCW (Used in HA,HB).       C54         C31       Metal mica: $33 \text{ pF} \pm 5\%$ 100 VDCW (Used in HC).       C55         C32       Metal mica: $33 \text{ pF} \pm 5\%$ 100 VDCW (Used in HB,HC).       C56         C33       Metal mica: $30 \text{ pF} \pm 5\%$ 100 VDCW (Used in HB,HC).       C57         C33       Metal mica: $20 \text{ pF} \pm 5\%$ 100 VDCW (Used in HB,HC).       C57         C33       Metal mica: $20 \text{ pF} \pm 5\%$ 100 VDCW (Used in HA,HE).       C57         C33       Metal mica: $20 \text{ pF} \pm 5\%$ 100 VDCW (Used in HA,HE).       C57         C34       Mica: $30 \text{ pF} \pm 5\%$ 500 VDCW (Used in HA,HE,HC).       C58         C35       Ceramic: $10 \text{ F} = 0.5\text{ pF} 500 VDCW, tempcoel 0±60PPM (Used in HA,HB).       C59         C36       Ceramic: 6 \text{ pF} \pm 0.5\text{ pF} 500 VDCW, temp coel0±60PPM (Used in HA,HB,HC).       C59         C37       Electrolytic: 22 \text{ H} \pm 10\% 40 VDCW (teed inHA,HB,HC).       C59         C38       Ceramic: 6 \text{ pF} \pm 0.5\text{ pF} 500 VDCW, temp coel0±60PPM (Used in HA,HB,HC).       C60         C41       Mica: 8 \text{ pF} \pm 0.5\text{ pF} 500 VDCW, temp coel0±60PPM (Used in HA,HB,HC).       C60         C41       Mica: 8 \text{ pF} \pm 0.5\text{ pF} 500 VDCW, temp coel0±60PPM (Used in HA,HB,HC).       C61         C41       Ceramic: 5 \text{ pF} \pm 0.5\text{ pF}$			1 ( )	C53	
HA, HB).       HA, HB).       C55         C31       Metal mica: 33 pF ±5% 100 VDCW (Used in HC).       C55         C32       Metal mica: 33 pF ±5% 100 VDCW (Used in HA).       C56         C33       Metal mica: 30 pF ±5% 100 VDCW (Used in HB, HC).       C57         C33       Metal mica: 20 pF ±5% 100 VDCW (Used in HB).       C57         C33       Metal mica: 21 pF ±5% 100 VDCW (Used in HC).       C57         C33       Metal mica: 24 pF ±5% 100 VDCW (Used in HC).       C57         C34       Mica: 30 pF ±5% 500 VDCW (Used in HA, HB, HC).       C58         C35       Ceramic: 10 pF 10.5pF 500 VDCW, temp coef 0:460PPM (Used in HA, HB).       C58         C36       Ceramic: 6 pF ±0.5pF 500 VDCW, temp coef 0:60PPM (Used in HA, HB, HC).       C59         C37       Electrolytic: 22 uF ±10% 40 VDCW (Used in HA, HB, HC).       C59         C38       Ceramic: 01 uF +80%, -20% 50 VDCW, temp coef 0:60PPM (Used in HA, HB, HC).       C59         C39       Ceramic: 01 uF +55p 500 VDCW, temp coef 0:60PPM (Used in HA, HB, HC).       C60         C41       Mica: 8 pF ±0.5pF 50 VDCW, temp coef 0:60PPM (Used in HA, HB, HC).       C60         C41       Mica: 6 pF ±0.5pF 50 VDCW, temp coef 0:60PPM (Used in HA, HB, HC).       C61         C41       Mica: 6 pF ±0.5pF 50 V				C54	
HC).     Height mice: 43 pF ±5% 100 VDCW (Used in HA).     C56       C32     Metal mice: 36 pF ±5% 100 VDCW (Used in HB).     C56       C33     Metal mice: 30 pF ±5% 100 VDCW (Used in HB).     C57       C33     Metal mice: 24 pF ±5% 100 VDCW (Used in HA).     C57       C33     Metal mice: 24 pF ±5% 100 VDCW (Used in HA).     C57       C34     Metal mice: 24 pF ±5% 100 VDCW (Used in HA).     C58       C35     Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef     C59       C36     Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef     C59       C36     Ceramic: 6 pF ±0.5pF 500 VDCW, temp coef     C59       C36     Ceramic: 0 µF ±05%.20% 50 VDCW, temp coef     C59       C37     Electrolytic: 22 µF ±10% 40 VDCW (Used in HA).     C59       C38     Ceramic: 0 µF ±05%.500 VDCW, temp coef     C60       C39     Ceramic: 0 µF ±05%.500 VDCW, temp coef     C60       C40     Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef     C60       C41     Mica: 8 pF ±0.5pF 500 VDCW, temp coef     C60       C41     Mica: 8 pF ±0.5pF 500 VDCW, temp coef     C60       C41     Ceramic: 12 pF ±3% 500 VDCW, temp coef     C61       C41     Ceramic: 12 pF ±0.5pF 50 VDCW, temp coef			HA,HB).		
HA).     C32     Metal mica: 36 pF ±5% 100 VDCW (Used in HB,HC).     C56       C33     Metal mica: 30 pF ±5% 100 VDCW (Used in HA).     C57       C33     Metal mica: 27 pF ±5% 100 VDCW (Used in HA).     C57       C33     Metal mica: 24 pF ±5% 100 VDCW (Used in HA).     C57       C34     Mica: 90 pF ±5% 500 VDCW (Used in HA).     C58       C35     Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef     C59       C36     Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef     C59       C36     Ceramic: 6 pF ±0.5pF 500 VDCW, temp coef     C59       C36     Ceramic: 6 pF ±0.5pF 500 VDCW, temp coef     C59       C37     Electrolytic: 22 µF ±10% 40 VDCW (Used in C59     C59       C38     Ceramic: 0.1 µF +80%, -20% 50 VDCW, temp coef     C59       C39     Ceramic: 10 pF ±5% 500 VDCW, temp coef     C60       C41     Mica: 8 pF ±0.5pF 500 VDCW, temp coef     C60       C41     Mica: 8 pF ±0.5pF 500 VDCW, temp coef     C60       C41     Mica: 8 pF ±0.5pF 500 VDCW, temp coef     C61       C41     Mica: 8 pF ±0.5pF 500 VDCW, temp coef     C61       C41     Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef     C61       C41     Ceramic: 10 pF ±0.5pF 500 VDCW, temp co	C31			C55	
C33     Metal mica: 30 pF ±5% 100 VDCW (Used in HA).     C57       C33     Metal mica: 27 pF ±5% 100 VDCW (Used in HB).     C57       C33     Metal mica: 27 pF ±5% 100 VDCW (Used in HC).     C57       C33     Metal mica: 24 pF ±5% 100 VDCW (Used in HC).     C57       C34     Mica: 90 pF ±5% 500 VDCW (Used in HA,HB,HC).     C58       C35     Ceramic: 10 pF ±0.5pF 500 VDCW, temp cof 0±60PPM (Used in HA,HB).     C58       C36     Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C59       C36     Ceramic: 6 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C59       C37     Electrolytic: 22 µF ±10% 40 VDCW (Used in C59     C59       C38     Ceramic: 10 µF ±5% 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C59       C39     Ceramic: 10 µF ±5% 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C60       C41     Mica: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in LA,HB,HC).     C61       C41     Mica: 6 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in LA,HB,HC).     C61       C41     Ceramic: 10 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in LA,LB).     C61       C41     Ceramic: 6 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used in LA,LB,LC).     C61       C	C32			C56	
HA).     HA).     C57       C33     Metal mica: 27 pF ±5% 100 VDCW (Used in HC).     C57       C34     Mica: 90 pF ±5% 500 VDCW (Used in HA,HB,HC).     C58       C35     Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB).     C58       C36     Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB).     C59       C36     Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C59       C37     Electrolytic: 22 µF ±10% 40 VDCW (Used in HA,HB,HC).     C59       C38     Ceramic: 10 pF ±3% 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C59       C39     Ceramic: 10 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C59       C40     Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C60       C41     Mica: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C60       C41     Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in LA,LB).     C61       C41     Mica: 6 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in LA,LB).     C61       C41     Ceramic: 7 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used in HA,HB,HC).     C62       C44     Ceramic: 7 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used in HA,HB,HC).     C62       C44     Ceramic: 5 pF ±0.5pF 50 VDCW,	C32			C56	
C33     Metal mica: 24 pF ±5% 100 VDCW (Used in HC).     C57       C34     Mica: 90 pF ±5% 500 VDCW (Used in HA,HB,HC).     C58       C35     Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB).     C59       C35     Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C59       C36     Ceramic: 0 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C59       C37     Electrolytic: 22 µF ±10% 40 VDCW (Used in HA,HB,HC).     C59       C38     Ceramic: 0 µF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C59       C39     Ceramic: 0 µF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C60       C40     Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C60       C41     Mica: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).     C60       C41     Ceramic: 12 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in LA,LB,LC).     C61       C41     Ceramic: 12 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in LA,LB,LC).     C61       C41     Ceramic: 5 pF ±0.5pF 50 VDCW, temp coef 0±60PPM (Used in LA,LB,LC).     C62       C44     Ceramic: 5 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used in HB,HC).     C62       C44     Ceramic: 5 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used in HA,HC).     C63	C33			C57	
HC).       C34       Mica: 90 pF $\pm 5\%$ 500 VDCW (Used in HA, HB, HC).       C58         C35       Ceramic: 10 pF $\pm 0.5pF$ 500 VDCW, temp coef $0\pm 60PPM$ . (Used in HA, HB).       C58         C35       Ceramic: 6 pF $\pm 0.5pF$ 500 VDCW, temp coef $0\pm 60PPM$ (Used in HA, HB), HC).       C59         C36       Ceramic: 6 pF $\pm 0.5pF$ 500 VDCW, temp coef $0\pm 60PPM$ (Used in HA, HB, HC).       C59         C37       Electrolytic: 22 µF $\pm 10\%$ 40 VDCW (Used in HA, HB, HC).       C59         C38       Ceramic: 0.1 µF $\pm 80\%$ , $-20\%$ 50 VDCW, temp coef $\pm 30\%$ , $-80\%$ (Used in HA, HB, HC).       C59         C39       Ceramic: 10 pF $\pm 5\%$ 500 VDCW, temp coef $0\pm 60PPM$ (Used in HA, HB, HC).       C60         C41       Mica: 8 pF $\pm 0.5pF$ 500 VDCW, temp coef $0\pm 60PPM$ (Used in HA, HB, HC).       C60         C41       Mica: 6 pF $\pm 0.5pF$ 500 VDCW, temp coef $0\pm 60PPM$ (Used in LA, LB).       C61         C41       Ceramic: 10 pF $\pm 0.5pF$ 500 VDCW, temp coef $0\pm 60PPM$ (Used in LA, LB).       C61         C41       Ceramic: 50 pF $\pm 0.5pF$ 50 VDCW, temp coef $0\pm 30PPM$ . (Used in HA, LC).       C62         C44       Ceramic: 50 pF $\pm 0.5pF$ 50 VDCW, temp coef $0\pm 30PPM$ . (Used in HB, HC).       C62         C44       Ceramic: 6 pF $\pm 0.5pF$ 50 VDCW, temp coef $0\pm 30PPM$ (Used in HB, HC).       C63         C45       Ceramic: 5 pF $\pm 0.5pF$ 5	C33			C57	
C34       Mica: 90 pF ±5% 500 VDCW (Used in HA,HB,HC).       C58         C35       Ceramic: 10 pF ±0.5pF 500 VDCW, temp coel 0±60PPM. (Used in HA,HB).       C58         C35       Ceramic: 8 pF ±0.5pF 500 VDCW, temp coel 0±60PPM (Used in HA,HB,HC).       C59         C36       Ceramic: 8 pF ±0.5pF 500 VDCW, temp coel 0±60PPM (Used in HA,HB,HC).       C59         C37       Electrolytic: 22 µF ±10% 40 VDCW (Used in HA,HB,HC).       C59         C38       Ceramic: 0.1 µF ±80%, 20% 50 VDCW, temp coel ±30%, 80% (Used in HA,HB,HC).       C60         C39       Ceramic: 10.1 µF ±80%, 500 VDCW, temp coel 0±60PPM (Used in HA,HB,HC).       C60         C41       Mica: 8 pF ±0.5pF 500 VDCW, temp coel 0±60PPM (Used in HA,HB,HC).       C60         C41       Mica: 6 pF ±0.5pF 50 VDCW, (Used in HA, HB).       C60         C41       Ceramic: 12 pF ±5% 500 VDCW, temp coel 0±60PPM (Used in LA,LB).       C61         C41       Ceramic: 6 pF ±0.5pF 50 VDCW, temp coel 0±60PPM (Used in LA,LB).       C61         C44       Ceramic: 7 pF ±0.5pF 50 VDCW, temp coel 0±30PPM (Used in HA,HC).       C62         C44       Ceramic: 5 pF ±0.5pF 50 VDCW, temp coel 0±30PPM (Used in HA,HC).       C63         C44       Ceramic: 5 pF ±0.5pF 50 VDCW, temp coel 0±30PPM (Used in HA,HC).       C63         C45       Ceramic: 5 pF ±0.5pF 50	C33		Metal mica: 24 pF ±5% 100 VDCW (Used in	C57	
C35       Ceramic: 10 pF ±0.5pF 500 VDCW, temp coef 0±60PPM. (Used in HA,HB).       C58         C35       Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HC).       C59         C36       Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).       C59         C37       Electrolytic: 22 µF ±10% 40 VDCW (Used in HA,HB,HC).       C59         C38       Ceramic: 0.1 µF +80%,-20% 50 VDCW, temp coef ±30%, 40% (Used in HA,HB,HC).       C59         C39       Ceramic: 100 pF ±5% 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).       C60         C40       Ceramic: 8.0 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in HA,HB,HC).       C60         C41       Mica: 8 pF ±0.5pF 500 VDCW, (Used in HB).       C60         C41       Mica: 8 pF ±0.5pF 500 VDCW, (Used in HA,HB).       C60         C41       Ceramic: 10 pF ±0.5pF 500 VDCW, (Used in HA,HB).       C61         C41       Ceramic: 6 pF ±0.5pF 500 VDCW, temp coef 0±60PPM (Used in LA,LB).       C61         C44       Ceramic: 6 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used in HA).       C62         C44       Ceramic: 7 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used in HA).       C63         C45       Ceramic: 6 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used in HA).       C63         C45       Ceramic: 7 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used	C34		Mica: 90 pF ±5% 500 VDCW (Used in	C58	
C35       Ceramic: 8 pF $\pm 0.5pF$ 500 VDCW, temp coef 0±60PPM (Used in HC).       C59         C36       Ceramic: 6 pF $\pm 0.5pF$ 500 VDCW, temp coef 0±60PPM (Used in HA, HB, HC).       C59         C37       Electrolytic: 22 µF $\pm 10\%$ 40 VDCW (Used in HA, HB, HC).       C59         C38       Ceramic: 0.1 µF $\pm 80\%$ , 20% 50 VDCW, temp coef $\pm 30\%$ , $= 80\%$ (Used in HA, HB, HC).       C59         C39       Ceramic: 100 pF $\pm 5\%$ 500 VDCW, temp coef 0\pm60PPM (Used in HA, HB, HC).       C60         C40       Ceramic: 8 pF $\pm 0.5pF$ 500 VDCW, temp coef 0\pm60PPM (Used in HA, HB, HC).       C60         C41       Mica: 8 pF $\pm 0.5pF$ 500 VDCW, (used in HB).       C60         C41       Mica: 6 pF $\pm 0.5pF$ 500 VDCW, temp coef 0\pm60PPM (Used in LA, LB).       C61         C41       Ceramic: 10 pF $\pm 0.5pF$ 500 VDCW, temp coef 0 $\pm 00PPM$ (Used in LA, LB).       C61         C41       Ceramic: 10 pF $\pm 0.5pF$ 50 VDCW, temp coef 0 $\pm 30PPM$ (Used in HA).       C62         C44       Ceramic: 2 pF $\pm 0.5pF$ 50 VDCW, temp coef 0 $\pm 30PPM$ (Used in HA).       C62         C44       Ceramic: 7 pF $\pm 0.5pF$ 50 VDCW, temp coef 0 $\pm 30PPM$ (Used in HA).       C63         C45       Ceramic: 7 pF $\pm 0.5pF$ 50 VDCW, temp coef 0 $\pm 30PPM$ (Used in HA).       C63         C45       Ceramic: 7 pF $\pm 0.5pF$ 50 VDCW, temp coef 0 $\pm 30PPM$ (Used in HA).       C64	C35			C58	
C36       Ceramic: $6 p \pm 0.5 pF 500 VDCW, temp coef 0 \pm 60PPM (Used in HA,HB,HC).       C59         C37       Electrolytic: 22 µF ±10% 40 VDCW (Used in HA,HB,HC).       C59         C38       Ceramic: 0.1 µF +80%,-20% 50 VDCW, temp coef +30%, -80% (Used in HA,HB,HC).       C59         C39       Ceramic: 100 pF ±5% 500 VDCW, temp coef 0 ±60PPM (Used in HA,HB,HC).       C60         C40       Ceramic: 8 pF ±0.5 pF 500 VDCW, temp coef 0 ±60PPM (Used in HA,HB,HC).       C60         C41       Mica: 8 pF ±0.5 pF 500 VDCW, (Used in HB).       C60         C41       Mica: 8 pF ±0.5 pF 500 VDCW, temp coef 0 ±60PPM (Used in LA,LB).       C61         C41       Ceramic: 10 pF ±5% 500 VDCW, temp coef 0 ±60PPM (Used in LA,LB).       C61         C41       Ceramic: 6 pF ±0.5 pF 50 VDCW, temp coef 0 ±30PPM (Used in LA,LB).       C61         C44       Ceramic: 7 pF ±0.5 pF 50 VDCW, temp coef 0 ±30PPM. (Used in HA,HC).       C62         C44       Ceramic: 7 pF ±0.5 pF 50 VDCW, temp coef 0 ±30PPM. (Used in HA,LB,LC).       C63         C45       Ceramic: 6 pF ±0.5 pF 50 VDCW, temp coef 0 ±30PPM (Used in HA,LB,LC).       C64         C45       Ceramic: 7 pF ±0.5 pF 50 VDCW, temp coef 0 ±30PPM (Used in HA).       C64         C45       Ceramic: 8 pF ±0.5 pF 50 VDCW, temp coef 0 ±30 PPM. (Used in HA).       C64         $	C35		Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef	C59	
C37       Electrolytic: $22 \ \mu F \pm 10\% 40 \ VDCW \ (Used in HA, HB, HC).$ C59         C38       Ceramic: $0.1 \ \mu F + 80\%, -20\% 50 \ VDCW, temp \ C59       C59         C39       Ceramic: 100 \ pF \pm 5\% 500 \ VDCW, temp \ coef \ 0\pm 60PPM \ (Used in HA, HB, HC).       C60         C40       Ceramic: 3 \ pF \pm 0.5 \ pF 500 \ VDCW, temp \ coef \ 0\pm 60PPM \ (Used in HA, HB, HC).       C60         C41       Mica: 8 \ pF \pm 0.5 \ pF 500 \ VDCW, \ (Used in HB).       C60         C41       Mica: 6 \ pF \pm 0.5 \ pF 500 \ VDCW, \ (Used in HB).       C60         C41       Mica: 6 \ pF \pm 0.5 \ pF 500 \ VDCW, \ (Used in HB).       C60         C41       Mica: 6 \ pF \pm 0.5 \ pF 500 \ VDCW, \ (Used in HA, HB).       C61         C41       Ceramic: 12 \ pF \pm 5\% \ 500 \ VDCW, \ temp \ coef \ 0\pm 60PPM \ (Used in LA, LB).       C61         C41       Ceramic: 6 \ pF \pm 0.5 \ pF 50 \ VDCW, \ temp \ coef \ 0\pm 30PPM \ (Used in HA).       C62         C44       Ceramic: 5 \ pF \pm 0.5 \ pF 50 \ VDCW, \ temp \ coef \ 0\pm 30PPM \ (Used in HA, HC).       C62         C44       Ceramic: 5 \ pF \pm 0.5 \ pF 50 \ VDCW, \ temp \ coef \ 0\pm 30PPM \ (Used in HA, LB, LC).       C63         C44       Ceramic: 5 \ pF \pm 0.5 \ pF 50 \ VDCW, \ temp \ coef \ 0\pm 30 \ PPM \ (Used in HA).       C63         C45       Ceramic: 5 \ pF \pm 0.5 \ pF 50 \ VDCW, \ temp \ coef \$	C36		Ceramic: 6 pF ±0.5pF 500 VDCW, temp coef	C59	
C38       Ceramic: $0.1 \ \mu F + 80\%, -20\% 50 \ VDCW, temp coef coef + 30\%, -80\% (Used in HA,HB,HC).       C59         C39       Ceramic: 100 \ pF \pm 5\% 500 \ VDCW, temp coef 0\pm 60 \ PDM (Used in HA,HB,HC).       C60         C40       Ceramic: 8 \ pF \pm 0.5 \ pF 500 \ VDCW, temp coef 0\pm 60 \ PDM (Used in HA,HB,HC).       C60         C41       Mica: 8 \ pF \pm 0.5 \ pF 500 \ VDCW, (Used in HB).       C60         C41       Mica: 6 \ pF \pm 0.5 \ pF 500 \ VDCW, (Used in HB).       C60         C41       Mica: 6 \ pF \pm 0.5 \ pF 500 \ VDCW, (Used in HA,HB,HC).       C61         C41       Ceramic: 12 \ pF \pm 5\% 500 \ VDCW, temp coef 0\pm 60 \ PPM (Used in LA,LB).       C61         C41       Ceramic: 10 \ pF \pm 0.5 \ pF 500 \ VDCW, temp coef 0\pm 60 \ PPM (Used in LA,LB).       C61         C44       Ceramic: 5 \ pF \pm 0.5 \ pF 50 \ VDCW, temp coef 0\pm 30 \ PPM (Used in HA).       C62         C44       Ceramic: 5 \ pF \pm 0.5 \ pF 50 \ VDCW, temp coef 0\pm 30 \ PPM. (Used in HB,HC).       C63         C44       Ceramic: 5 \ pF \pm 0.5 \ pF 50 \ VDCW, temp coef 0\pm 30 \ PPM. (Used in HA,HC).       C63         C45       Ceramic: 6 \ pF \pm 0.5 \ pF 50 \ VDCW, temp coef 0\pm 30 \ PPM. (Used in HB,HC).       C64         C45       Ceramic: 6 \ pF \pm 0.5 \ pF 50 \ VDCW, temp coef 0\pm 30 \ PPM. (Used in HA).       C64         C45       Ceramic: 6 \ pF \pm 0.5 \ pF 50 \ VDC$	C37		Electrolytic: 22 $\mu$ F ±10% 40 VDCW (Used in	C59	
C39Ceramic: 100 pF $\pm$ 5% 500 VDCW, temp coef $0\pm$ 60PPM (Used in HA,HB,HC).C60C40Ceramic: 8 pF $\pm$ 0.5pF 500 VDCW (temp coef $0\pm$ 60PPM (Used in HA,HB,HC).C60C41Mica: 8 pF $\pm$ 0.5pF 50 VDCW (Used in HB).C60C41Mica: 6 pF $\pm$ 0.5pF 50 VDCW, (Used in HB).C60C41Ceramic: 12 pF $\pm$ 5% 500 VDCW, temp coef $0\pm$ 60PPM (Used in LA,LB).C61C41Ceramic: 10 pF $\pm$ 0.5pF 50 VDCW, temp coef $0\pm$ 60PPM (Used in LA,LB).C61C41Ceramic: 6 pF $\pm$ 0.5pF 50 VDCW, temp coef $0\pm$ 30PPM (Used in LA).C62C44Ceramic: 6 pF $\pm$ 0.5pF 50 VDCW, temp coef $0\pm$ 30PPM (Used in LA,LB,LC).C63C44Ceramic: 7 pF $\pm$ 0.5pF 50 VDCW, temp coef $0\pm$ 30PPM (Used in LA,LB,LC).C63C45Ceramic: 6 pF $\pm$ 0.5pF 50 VDCW, temp coef $0\pm$ 30PPM (Used in HA).C63C45Ceramic: 7 pF $\pm$ 0.5pF 50 VDCW, temp coef $0\pm$ 30PPM (Used in HA).C64C47 and C48Ceramic: 8 pF $\pm$ 0.5 pF 50 VDCW, temp coef $0\pm$ 30 PPM.C64C49Ceramic: 8 pF $\pm$ 0.5 pF 50 VDCW, temp coef $0\pm$ 30 PPM.C64C49Ceramic: 7 pF $\pm$ 0.5 pF 50 VDCW, temp coef $0\pm$ 30 PPM.C64C49Ceramic: 7 pF $\pm$ 0.5 pF 50 VDCW, temp coef $0\pm$ 30 PPM.C64C49Ceramic: 7 pF $\pm$ 0.5 pF 50 VDCW, temp coef $0\pm$ 30 PPM.C64C49Ceramic: 7 pF $\pm$ 0.5 pF 50 VDCW, temp coef $0\pm$ 30 PPM.C64C49Ceramic: 7 pF $\pm$ 0.5 pF 50 VDCW, temp coef $0\pm$ 30 PPM.C64C49Ceramic: 7 pF $\pm$ 0.5 pF 50 VDCW, temp coef $0\pm$ 30 PPM.C64C49Cera	C38		Ceramic: 0.1 µF +80%,-20% 50 VDCW, temp	C59	
C40Ceramic: $8 p \pm 10.5 p F 500 VDCW, temp coef0±60PPM (Used in HA,HB,HC).C60C41Mica: 8 p \pm 10.5 p F 500 VDCW (Used in HB).C60C41Mica: 6 p \pm 10.5 p F 50 VDCW, (Used inHA,HB).C60C41Ceramic: 12 p F \pm 5\% 500 VDCW, (used inHA,HB).C61C41Ceramic: 12 p F \pm 5\% 500 VDCW, temp coef0\pm 60PPM (Used in LA,LB).C61C41Ceramic: 10 p F \pm 0.5 p F 500 VDCW, temp coef0\pm 60PPM (Used in LA,LB).C61C44Ceramic: 6 p F \pm 0.5 p F 50 VDCW, temp coef0\pm 30PPM (Used in HA).C62C44Ceramic: 5 p F \pm 0.5 p F 50 VDCW, temp coef0\pm 30PPM (Used in HB,HC).C62C44Ceramic: 7 p \pm 0.5 p F 50 VDCW, temp coef0\pm 30PPM. (Used in LA,LB,LC).C63C45Ceramic: 6 p \pm 0.5 p F 50 VDCW, temp coef0\pm 30PPM (Used in HA).C63C45Ceramic: 5 p \pm 0.5 p F 50 VDCW, temp coef0 \pm 30PPM (Used in HB,HC).C64C47Ceramic: 100 p F \pm 5\% 50 VDCW, temp coef0 \pm 30 PPM. (Used in HB,HC).C64C49Ceramic: 8 p \pm 10.5 p F, 50 VDCW, temp coef0 \pm 30 PPM. (Used in HA).C64C49Ceramic: 7 p \pm 0.5 p F, 50 VDCW, temp coef0 \pm 30 PPM. (Used in HA).C64C49Ceramic: 7 p \pm 0.5 p F, 50 VDCW, temp coef0 \pm 30 PPM. (Used in HB).C64C49Ceramic: 100 p F \pm 0.5 p F, 50 VDCW, temp coef0 \pm 30 PPM. (Used in HB).C64C49Ceramic: 100 p F \pm 0.5 p F, 50 VDCW, temp coef0 \pm 30 PPM. (Used in HB).C64C49Ceramic: 100 p F \pm 0.5 p F, 50 VDCW, temp coef0 \pm 30 PPM. (Used in HB).C64C$	C39		Ceramic: 100 pF ±5% 500 VDCW, temp coef	C60	
C41Mica: 6 pF $\pm 0.5$ pF 50 VDCW, (Used in HA,HB).C60C41Ceramic: 12 pF $\pm 5\%$ 500 VDCW, temp coef $0\pm 60$ PPM (Used in LA,LB).C61C41Ceramic: 10 pF $\pm 0.5$ pF 500 VDCW, temp coef $0\pm 60$ PPM (Used in LC).C61C44Ceramic: 6 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM (Used in HA).C62C44Ceramic: 5 pF $\pm 0.25$ pF 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB,HC).C62C44Ceramic: 7 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM. (Used in LA,LB,LC).C63C45Ceramic: 6 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HA,HS,LC).C63C45Ceramic: 5 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB,HC).C64C47 and C48Ceramic: 8 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB,HC).C64C49Ceramic: 8 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HA).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HA).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in LC).C64C49Ceramic: 7 pF $\pm 0.5$ pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in LC).C64C50Ceramic: 4 pE 4 0 25 pF $\pm 0.5$ pF 50 VDCW, temp coef 0 $\pm 30$ PPM (Used in LC).C64	C40		Ceramic: 8 pF ±0.5pF 500 VDCW, temp coef	C60	
HA,HB).C60C41Ceramic: 12 pF $\pm 5\%$ 500 VDCW, temp coef $0\pm 60$ PPM (Used in LA,LB).C61C41Ceramic: 10 pF $\pm 0.5$ pF 500 VDCW, temp coef $0\pm 60$ PPM (Used in LC).C61C44Ceramic: 6 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM (Used in HA).C62C44Ceramic: 5 pF $\pm 0.25$ pF 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB,HC).C62C44Ceramic: 7 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM. (Used in LA,LB,LC).C63C45Ceramic: 6 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM (Used in HA,HC).C63C45Ceramic: 5 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM (Used in HB,HC).C63C45Ceramic: 5 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM (Used in HB,HC).C64C47 and C48Ceramic: 8 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM.C64C49Ceramic: 7 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HA).C64C49Ceramic: 7 pF $\pm 0.5$ pF $50$ VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 7 pF $\pm 0.5$ pF $50$ VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 7 pF $\pm 0.5$ pF $50$ VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 7 pF $\pm 0.5$ pF $50$ VDCW, temp coef $0\pm 30$ PPM. (Used in LC).C64C49Ceramic: 7 pF $\pm 0.5$ pF $50$ VDCW, temp coef $0\pm 30$ PPM. (Used in LC).C64	C41		Mica: 8 pF $\pm$ 0.5pF 500 VDCW (Used in HB).	C60	
$0\pm 60$ PPM (Used in LA,LB).C61C41Ceramic: 10 pF $\pm 0.5pF$ 500 VDCW, temp coef $0\pm 60$ PPM (Used in LC).C61C44Ceramic: 6 pF $\pm 0.5pF$ 50 VDCW, temp coef $0\pm 30$ PPM (Used in HA).C62C44Ceramic: 5 pF $\pm 0.25pF$ 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB,HC).C62C44Ceramic: 7 pF $\pm 0.5pF$ 50 VDCW, temp coef $0\pm 30$ PPM. (Used in LA,LB,LC).C63C45Ceramic: 6 pF $\pm 0.5pF$ 50 VDCW, temp coef $0\pm 30$ PPM (Used in LA,LB,LC).C63C45Ceramic: 5 pF $\pm 0.5pF$ 50 VDCW, temp coef $0\pm 30$ PPM (Used in HB,HC).C63C45Ceramic: 5 pF $\pm 0.5pF$ 50 VDCW, temp coef $0\pm 30$ PPM (Used in HB,HC).C64C47Ceramic: 100 pF $\pm 5\%$ 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB,HC).C64C49Ceramic: 8 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HA).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 10.5 pF $\pm 0.25$ pF, 50 VDCW, temp coef $0\pm 30$ PPM (Used in LC).C64C49Ceramic: $\pm 0.5$ pF $\pm 0.25$ pF, 50 VDCW, temp coef $0\pm 30$ PPM (Used in LC).C64C49Ceramic: $\pm 0.5$ pF $\pm 0.25$ pF, 50 VDCW, temp coef $0\pm 30$ PPM (Used in LC).C64	C41			C60	
Coef $0\pm 60PPM$ (Used in LC).C61C44Ceramic: 6 pF $\pm 0.5pF$ 50 VDCW, temp coef $0\pm 30PPM$ (Used in HA).C62C44Ceramic: 5 pF $\pm 0.25pF$ 50 VDCW, temp coef $0\pm 30PPM$ . (Used in HB,HC).C62C44Ceramic: 7 pF $\pm 0.5pF$ 50 VDCW, temp coef $0\pm 30PPM$ . (Used in LA,LB,LC).C63C45Ceramic: 6 pF $\pm 0.5pF$ 50 VDCW, temp coef $0\pm 30PPM$ (Used in HA).C63C45Ceramic: 5 pF $\pm 0.5pF$ 50 VDCW, temp coef $0\pm 30PPM$ (Used in HA).C63C45Ceramic: 5 pF $\pm 0.5pF$ 50 VDCW, temp coef $0\pm 30PPM$ (Used in HB,HC).C64C47Ceramic: 100 pF $\pm 5\%$ 50 VDCW, temp coef $0\pm 30 PPM$ .C64C49Ceramic: 8 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HA).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in LC).C64C50Ceramic: 4 np H 20 5 pF 50 VDCW, temp coef 0 $\pm 30$ PPM (Used in LC).C64	C41			C61	
$0\pm 30$ PPM (Úsed in HA).C62C44Ceramic: 5 pF $\pm 0.25$ pF 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB,HC).C62C44Ceramic: 7 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM. (Used in LA,LB,LC).C63C45Ceramic: 6 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM (Used in HA).C63C45Ceramic: 5 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM (Used in HB,HC).C63C45Ceramic: 100 pF $\pm 5\%$ 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB,HC).C64C47 and C48Ceramic: 8 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HA).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in LC).C64C50Ceramic: 4 pF 4 0 25 pF, 50 VDCW, temp coef 0 $\pm 30$ PPM (Used in LC).C64	C41			C61	
$0\pm 30$ PPM. (Used in HB,HC).C62C44Ceramic: 7 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM. (Used in LA,LB,LC).C63C45Ceramic: 6 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM (Used in HA).C63C45Ceramic: 5 pF $\pm 0.5$ pF 50 VDCW, temp coef $0\pm 30$ PPM (Used in HB,HC).C64C47Ceramic: 100 pF $\pm 5\%$ 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB,HC).C64C47Ceramic: 8 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB,HC).C64C48Ceramic: 8 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HA).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 10.5 pF $\pm 0.25$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: $\pm 0.5$ pF $\pm 0.25$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in LC).C64C50Ceramic: $\pm 0.5$ pF $\pm 0.25$ pF, 50 VDCW, tempC64	C44			C62	
$0\pm 30$ PPM. (Used in LA,LB,LC).C63C45Ceramic: 6 pF ±0.5pF 50 VDCW, temp coef $0\pm 30$ PPM (Used in HA).C63C45Ceramic: 5 pF ±0.5pF 50 VDCW, temp coef $0\pm 30$ PPM (Used in HB,HC).C64C47Ceramic: 100 pF ±5% 50 VDCW, temp coef $0\pm 30$ PPM.C64C48Ceramic: 8 pF ±0.5 pF, 50 VDCW, temp coef $0\pm 30$ PPM.C64C49Ceramic: 8 pF ±0.5 pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HA).C64C49Ceramic: 7 pF ±0.5 pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 7 pF ±0.5 pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: ±0.5 pF ±0.25 pF, 50 VDCW, temp coef $0\pm 30$ PPM (Used in LC).C64C50Ceramic: ±0.5 pF ±0.25 pF, 50 VDCW, temp coef 0±30 PPM (Used in LC).C64	C44			C62	
0±30PPM (Used in HA).       C63         C45       Ceramic: 5 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used in HB,HC).       C64         C47       Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM.       C64         C48       C64       C64         C49       Ceramic: 8 pF ±0.5 pF, 50 VDCW, temp coef 0±30 PPM. (Used in HA).       C64         C49       Ceramic: 7 pF ±0.5 pF, 50 VDCW, temp coef 0±30 PPM. (Used in HA).       C64         C49       Ceramic: 7 pF ±0.5 pF, 50 VDCW, temp coef 0±30 PPM. (Used in HB).       C64         C49       Ceramic: 20.5 pF ±0.25 pF, 50 VDCW, temp coef 0±30 PPM. (Used in LC).       C64         C50       Ceramic: 4 pE +0.25 pF, 50 VDCW, temp       C64	C44			C63	
0±30PPM (Úsed in HB,HC).       C64         C47       Ceramic: 100 pF ±5% 50 VDCW, temp coef       C64         and       0±30 PPM.       C64         C48       C49       Ceramic: 8 pF ±0.5 pF, 50 VDCW, temp coef       C64         C49       Ceramic: 7 pF ±0.5 pF, 50 VDCW, temp coef       C64         C49       Ceramic: 7 pF ±0.5 pF, 50 VDCW, temp coef       C64         C49       Ceramic: 7 pF ±0.5 pF, 50 VDCW, temp coef       C64         C49       Ceramic: ±0.5 pF ±0.25 pF, 50 VDCW, temp coef       C64         C49       Ceramic: ±0.5 pF ±0.25 pF, 50 VDCW, temp coef       C64         C50       Ceramic: ±0.7 pF ±0.25 pF, 50 VDCW, temp coef       C64	C45			C63	
C47 and C48Ceramic: 100 pF $\pm 5\%$ 50 VDCW, temp coef $0\pm 30$ PPM.C64C49Ceramic: 8 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HA).C64C49Ceramic: 7 pF $\pm 0.5$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: 10.5 pF $\pm 0.25$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in HB).C64C49Ceramic: $\pm 0.5$ pF $\pm 0.25$ pF, 50 VDCW, temp coef $0\pm 30$ PPM. (Used in LC).C64C50Ceramic: 4 pE $\pm 0.25$ pF $\pm 0.20$ VDCW tempC64	C45		Ceramic: 5 pF ±0.5pF 50 VDCW, temp coef 0±30PPM (Used in HB.HC).	C64	
C49       Ceramic: 8 pF ±0.5 pF, 50 VDCW, temp coef       C64         C49       Ceramic: 7 pF ±0.5 pF, 50 VDCW, temp coef       C64         C49       Ceramic: 7 pF ±0.5 pF, 50 VDCW, temp coef       C64         C49       Ceramic: ±0.5 pF ±0.25 pF, 50 VDCW, temp coef       C64         C49       Ceramic: ±0.5 pF ±0.25 pF, 50 VDCW, temp coef       C64         C50       Ceramic: ±0.7 pF ±0.25 pF, 50 VDCW, temp coef       C64			Ceramic: 100 pF ±5% 50 VDCW, temp coef	C64	
0±30 PPM. (Used in HA).       C64         C49       Ceramic: 7 pF ±0.5 pF, 50 VDCW, temp coef 0±30 PPM. (Used in HB).       C64         C49       Ceramic: ±0.5 pF ±0.25 pF, 50 VDCW, temp coef 0±30 PPM (Used in LC).       C64         C50       Ceramic: 4 pE ±0.25 pF, 50 VDCW, temp       C64				C64	
0±30 PPM. (Used in HB).       C64         C49       Ceramic: ±0.5 pF ±0.25 pF, 50 VDCW, temp coef 0±30 PPM (Used in LC).       C64         C50       Ceramic: 4 pE ±0.25 pF, 50 VDCW, temp       C64			0±30 PPM. (Used in HA).	C64	
coef 0±30 PPM (Used in LC). C50 Ceramic: 4 pE ±0.25 pE 50 VDCW temp			0±30 PPM. (Used in HB).	C64	
C50 Ceramic: 4 pE +0.25 pE 50 V/DCW temp	C49			C64	
coef 0±30 PPM (Used in HC).	C50			C65	
C50 Ceramic: 6 pF ±0.5 pF, 50 VDCW, temp coef 0±30 PPM (Used in LA,LB,LC). C65	C50			C65	

\*COMPONENTS, ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

PART NO.	DESCRIPTION
	Ceramic: 100 pF ±5%, 50 VDCW, temp coef 0±30 PPM.
	Ceramic: 1000 pF ±10% 50 VDCW, temp coef 0±15% ±15% (Used in HA,HB,HC).
	Ceramic: 100 pF $\pm$ 5% 50 VDCW, temp coef 0 $\pm$ 30PPM.
	Ceramic: 100 pF $\pm$ 5% 50 VDCW, temp coef 0 $\pm$ 30 PPM.
	Ceramic: 100 pF $\pm$ 5% 500 VDCW, temp coef 0 $\pm$ 60 PPM.
	Ceramic: 3 pF $\pm$ 0.25 pF 500 VDCW, temp coef 0 $\pm$ 120 PPM (Used in HA,HB).
	Ceramic: 4 pF ±0.25 pF 500 VDCW, temp coef 0±60 PPM (Used in LA,LB,LC,HC).
	Ceramic: 6 pF $\pm$ 0.5pF 500 VDCW, temp coef 0 $\pm$ 60 PPM (Used in HC).
	Ceramic: 5 pF $\pm$ 0.5pF 500 VDCW, temp coef 0 $\pm$ 60 PPM (Used in HB).
	Ceramic: 7 pF $\pm$ 0.5 pF 500 VDCW, temp coef 0 $\pm$ 60 PPM (Used in LA,LB,LC,HA).
	Ceramic: 3 pF ±0.25 pF 500 VDCW, temp coef 0±120 PPM (Used in LA,HA,HB).
	Ceramic: 2 pF ±0.25 pF 500 VDCW, temp coef 0±60 PPM (Used in LB,LC,HC).
	Ceramic:2 pF $\pm$ 0.25pF 500 VDCW, temp coef 0 $\pm$ 250 PPM (Used in HC).
	Ceramic: 3 pF $\pm$ 0.25 pF 500 VDCW, temp coef 0 $\pm$ 120 PPM (Used in HA,HB,LC).
	Ceramic: 5 pF ±0.25pF 500 VDCW, temp coef 0±60 PPM (Used in LA).
	Ceramic: 4 pF ±0.25 pF 500 VDCW, temp coef 0±60 PPM (Used in LB).
	Ceramic: 4 pF ±0.25 pF 500 VDCW, temp coef 0±60 PPM (Used in HC).
	Ceramic: 3 pF ±0.25 pF 500 VDCW, temp coef 0±120 PPM (Used in HA,HB).
	Ceramic: 6 pF ±0.25pF 500 VDCW, temp coef 0±60 PPM (Used in LA,LB).
	Ceramic: 7 pF $\pm$ 0.5pF 500 VDCW, temp coef 0 $\pm$ 60 PPM (Used in LC).
	Ceramic: 2 pF ±0.25 pF 500 VDCW, temp coef 0±60 PPM (Used in LA,HA,HB).
	Ceramic: 1 pF ±0.25 pF 500 VDCW, temp coef 0±60 PPM (Used in LB,LC,HC).
	Ceramic: 7 pF ±0.5 pF 500 VDCW, temp coef 0±60 PPM (Used in LA,LB,LC,HA).
	Ceramic: 6 pF ±0.5pF 500 VDCW, temp coef 0±60 PPM (Used in HB,HC).
	Ceramic: 4 pF ±0.25 pF 500 VDCW, temp coef 0±60 PPM (Used in LA,LB,LC,HA,HB).
	Ceramic: 3 pF ±0.25pF 500 VDCW, temp coef 0±120 PPM (Used in HC).
	Mica: 2 pF ±0.25pF 500 VDCW (Used in HB). Mica: 1.5 pF ±0.25pF 500 VDCW (Used in
	HC). Ceramic: 5 pF ±0.25pF 500 VDCW, temp coef 0±60 PPM (Used in LA)
	coef 0±60 PPM (Used in LA). Ceramic: 4 pF ±0.25 pF 500 VDCW, temp coef 0±60 PPM (Used in LB).
	Coramic: 3 pF $\pm 0.25$ pF 500 VDCW, temp coef 0 $\pm 120$ PPM (Used in LC).
	Mica: 3 pF $\pm$ 0.25pF 500 VDCW (Used in HA).
	Ceramic: 6 pF ±0.5pF 500 VDCW, temp coef 0±60 PPM (Used in HA,HB).
	Ceramic: 5 pF $\pm$ 0.5pF 500 VDCW, temp coef 0 $\pm$ 60 PPM (Used in LA).

### (Continued)

# PARTS LIST

SYMBOL	PART NO.	DESCRIPTION	SYMBOL	PART NO.	DESCRIPTION	SYMBOL	PART NO.	DESCRIPTION
C65		Ceramic: 4 pF ±0.25 pF 500 VDCW, temp	STWBOL	FART NO.				RESISTORS
C66		coef 0±60 PPM (Used in LB,LC,HC) Ceramic: 4 pF ±0.25 pF 500 VDCW, temp coef 0±60 PPM (Used in LA,LB).	HC1		INTEGRATED CIRCUITS RF Power Amplifier: sim to MITSUBISHI M57704M-38 (Used in LA.HA).	R1		Metal film: 470 ohms ±5%, 100 VDCW, 1/10W.
C66		Ceramic: 7 pF $\pm$ 0.5 pF 500 VDCW, temp coef 0 $\pm$ 60 PPM (Used in HB).	HC1		RF Power Amplifier: sim to MITSUBISHI M57704H-38 (Used in LB,HB).	R2 and R3		Metal film: 22 ohms ±5%, 100 VDCW, 1/10W.
C66		Ceramic: 3 pF ±0.25pF 500 VDCW, temp coef 0±120 PPM (Used in LC).	HC1		RF Power Amplifier: sim to MITSUBISHI M57704SH-38 (Used in LC,HC).	R4		Metal film: 470 ohms ±5%, 100 VDCW, 1/10W.
C66		Ceramic: 5 pF $\pm$ 0.25pF 500 VDCW, temp coef 0 $\pm$ 60 PPM (Used in HC).	IC1		Linear: Positive Voltage Regulator; sim to PANASONIC AN6541.	R5		Metal film: 24 ohms $\pm$ 5%, 350 VDCW, 3W (Used in HA,HB,HC,).
C67		Ceramic: 2 pF $\pm$ 0.25 pF 50 VDCW, temp coef 0 $\pm$ 30 PPM (Used in AH,BH,CH).	IC2		Linear, Dual OP Amp: sim to NEW JRC NJM3404AM.	R6 and R7		Metal film: 3.3K ohms $\pm$ 5%, 250 VDCW, 1W (Used in HA,HB,HC).
C67		Ceramic: 3 pF $\pm$ 0.25 pF 50 VDCW, temp coef $0\pm$ 30 PPM (Used in LA).	J3 J4		Connector. Connector.	R8		Metal film: 24 ohms ±1%, 500 VDCW, 1.5W (Used in HA,HB,HC,).
C68		Ceramic: 100 pF $\pm$ 5% 50 VDCW, temp coef 0 $\pm$ 30 PPM.			INDUCTORS	R10		Metal film: 82 ohms ±5%, 100 VDCW, 1/8W (Used in HA,HB,HC,).
C69		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM (Used in HA,HB,HC).	L1		Coil.	R10		Metal film: 68 ohms ±5%, 100 VDCW, 1/10W (Used in LA,LB,LC,).
C71		Tantalum: 10 $\mu$ F ±20%,35 VDCW (Used in HA,HB,HC).	L2 L2		Coil (Used in LA,HA,HB). Coil (Used in LB,LC,HC).	R11		Metal film: 120 ohms ±5%, 200 VDCW, 1/8W (Used in HA,HB,HC).
C71		Tantalum: 10 $\mu$ F ±20% 16 VDCW (Used in LA,LB,LC).	L3 L4		Coil. Coil.	R11 and		Metal film: 82 ohms ±5%, 100 VDCW, 1/10W (Used in LA,LB,LC,).
C72 C73		Electrolytic: 10 μF ±10%. Ceramic: 100 pF ±5% 500 VDCW, temp coef	L6		Coil (Used in HA,HB,HC).	R12		
010		0±60 PPM (Used in HA,HB,HC).	L6		Coil (Used in LA).	R12 and		Metal film: 82 ohms $\pm$ 5%, 200 VDCW, 1/8W (Used in HA,HB,HC).
C82		Ceramic: 100 pF $\pm$ 5% 50 VDCW, temp coef $0\pm$ 30 PPM.	L6		Coil (Used in LB,LC).	R13		Matal film: 68 abma 15% 400 \/DC\//
C83		Tantalum: 1 $\mu$ F ±20% 16 VDCW,	L7 L8		Coil.(Used in HA,HB,HC). Coil (Used in HA,HB,HC).	R13		Metal film: 68 ohms $\pm$ 5%, 100 VDCW, 1/10W (Used in LA,LB,LC,).
C84		Ceramic: 100 pF ±5% 50 VDCW, temp coef	L8 L9		Coil (Used in HA,HB,HC).	R14		Metal film: 12k ohms $\pm$ 5%, 100 VDCW, 1/10W (Used in HA).
thru C88		0±30 PPM.	L10		Coil (Used in HA,HB,HC).	R14		Metal film: 18k ohms $\pm$ 5%, 100 VDCW,
C89		Ceramic: 0.1 $\mu F~\pm 5\%$ 25 VDCW,	L11		Coil (Used in HA,HB,HC).			1/10W (Used in HB).
C90		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM (Used in HA,HB,HC).	L12		Coil (Used in HA,HB,HC).	R14		Metal film: 33k ohms $\pm$ 5%, 100 VDCW, 1/10W (Used in CH).
C91		Tantalum: 4.7 $\mu$ F ±10% 16 VDCW,	L13		Coil (Used in HA,HB,HC).	R14		Metal film: 2.7 ohms ±5%, 100 VDCW,
C92		Electrolytic: 100 µF ±20% 50 VDCW,	L14 L15		Coil (Used in HA,HB,HC). Coil (Used in HA,HB,HC).	DIE		1/10W (Used in LA,LB,LC,).
C93		Mica: 100 pF ±5% 500 VDCW,	L16		Coil.	R15		Metal film: 100 ohms ±5%, 100 VDCW, 1/10W.
C95		Electrolytic: $33 \mu\text{F} \pm 10\% 25 \text{VDCW}$ ,	L17		Coil.	R16		Metal film: 3.9K ohms ±5%, 100 VDCW,
C96		Ceramic: 15 pF ±5% 500 VDCW, temp coef 0±60 PPM (Used in HA,HB,HC).	L18		Coil.	R16		1/10W (Used in HA,HB). Metal film: 4.7K ohms ±5%, 100 VDCW,
C97		Mica: 22 pF $\pm$ 5% 100 VDCW (Used in HC).	L19		Coil (Used in HA,HB,HC).			1/10W (Used in HC).
C98		Mica: 90 pF ±5% 500 VDCW (Used in HA,HB,HC).	L19 L20 and		Coil (Used in LA,LB,LC). Coil.	R16		Metal film: 6.8K ohms ±5%, 100 VDCW, 1/10W (Used in LA,LB,LC).
C99		Ceramic: 100 pF ±5% 50 VDCW, temp coef 0±30 PPM (Used in LA,LB,LC).	L21		Coil.	R17 and R18		Metal film: 120 ohms ±5%, 250 VDCW, 1W (Used in HA,HB,HC,).
C151*		Ceramic: 330 pF ±5% 50 VDCW,(Used in LA, LB, LC, HA, HB) . 	L23 and		Coil (Used in HA,HB).	R17 and		Metal film: 180 ohms ±5%, 250 VDCW, 1W (Used in LA,LB,LC).
CD1		Silicon: fwd current 3A, 200 PIV; sim to MOTOROLA MR751 (Used in HA.HB.HC).	L24 L23		Coil (Used in HC).	R18 R19		Metal film: 47K ohms ±5%, 200 VDCW,
CD2		Ceramic: Varistor; sim to HOKURIKU 22ZR- 10D.	and L24			R20		1/4W. Metal film: 4.7K ohms ±5%, 100 VDCW, 1/10W.
CD3 and		Diode: sim to PANASONIC MA741-TX.	L23 L24		Coil (Used in LA,LB,LC,). Coil (Used in LA,LB,LC,).	R21		1/10W. Metal film: 680 ohms ±5%, 200 VDCW, 1/4W.
CD4		Diada (Llaad in LALRIC)	L25		Coil (Used in HA,HB,HC).	R35		Metal film: 10K ohms ±5%, 100 VDCW,
CD5 CD6		Diode.(Used in LA,LB,LC). Diode (Used in HA,HB,HC).	P1		Coaxial cable with connector (Used in LA,LB,LC).	Dee		1/10W.
CD7		Diode.	P1		Coaxial cable with connector (Used in HA,HB,HC).	R36		Metal film: 3.3K ohms $\pm$ 5%, 100 VDCW, 1/10W (Used in HA).
CD8		Diode (Used in HA,HB,HC).	P2		HA,HB,HC). Coaxial cable with connector (Used in	R36		Metal film: 1.8K ohms ±5%, 100 VDCW,
CD9		Diode.			LA,LB,LC).	R36		1/10W (Used in HB,HC). Metal film: 2.2K ohms ±5%, 100 VDCW,
CD10		Silicon: fast recovery (2 diodes in cathode common); sim to TOSHIBA 1SS184 TE85L.	P2		Coaxial cable with connector (Used in HA,HB,HC).	R37		1/10W. (Used in LA,LB,LC). Metal film: 2.2K ohms ±5%, 100 VDCW,
CD11 and CD12		Silicon: fast recovery, (RF Switch); sim to MITSUBISHI MI301				R38		1/10W. Metal film: 10K ohms ±5%, 100 VDCW,
0012								1/10W, (Used in HA,HB,HC).

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SYMBOL	PART NO.	DESCRIPTION
R38		Metal film: 8.2K ohms ±5%, 100 VDCW, 1/10W (Used in LA,LB,LC).
R39		Metal film: 2.7K ohms ±5%, 100 VDCW, 1/10W (Used in HA,HB,HC).
R39		Metal film: 3.9K ohms ±5%, 100 VDCW, 1/10W (Used in LA,LB,LC).
R40		Metal film: 27K ohms ±5%, 100 VDCW, 1/10W.
R41		Metal film: 2.2K ohms ±5%, 100 VDCW, 1/10W.
R42		Metal film: 47K ohms ±5%, 100 VDCW, 1/10W.
R43		Metal film: 1K ohms ±5%, 100 VDCW, 1/10W.
R44 and R45		Metal film: 820 ohms ±5%, 100 VDCW, 1/10W.
R46 and R47		Metal film: 470 ohms ±5%, 100 VDCW, 1/10W.
R48		Metal film: 10 ohms ±5%, 200 VDCW, 1/8W.
R49		Polyester: sim to MURATA PTH9M04BE222TS2F333.
R50		Metal film: 100K ohms ±5%, 100 VDCW, 1/10W.
R52*		Metal film: 50 ohms, 10W (Used in LA, LB, LC, HA, HB) .
RV1		Variable.
		TRANSISTOR
TR1		Silicon,NPN: sim to MITSUBISHI 2SC3102.
TR2 and TR3		Silicon,NPN: sim to MITSUBISHI 2SC4989 (Used in HA,HB,HC).
TR4		Silicon, PNP: sim to NEC 2SB624-T1B BV3.
TR5 and TR6		Silicon, PNP: sim to NEC 2SB596-T1B DV3.
TR7		Silicon PNP: sim to PANASONIC 2SB953A.
TR8		Silicon NPN: sim to PANASONIC 2SD1271-Q.
		WIRE
W1		Jumper wire: (Used in HA,HB,HC).
W3		Jumper wire: (Used in HA,HB,HC).

### PRODUCTION CHANGES

Changes in the equipment to improve or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number on the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for the description of parts affected by these revisions.

### REV. A - Power Amplifier Units 344A4573P1 & P2

To improve stability. Deleted capacitor C6. Changed capacitor C45 to 4.7  $\mu\text{F}$ 

### REV. A - Power Amplifier Units 344A4573P3, P4 & P5

To improve stability. Changed capacitor C12 from 36 pF to 47 pF metal mica. This improves matching to the final amplifier.

### REV. B- Power Amplifier Units 344A4573P3, P4 & P5

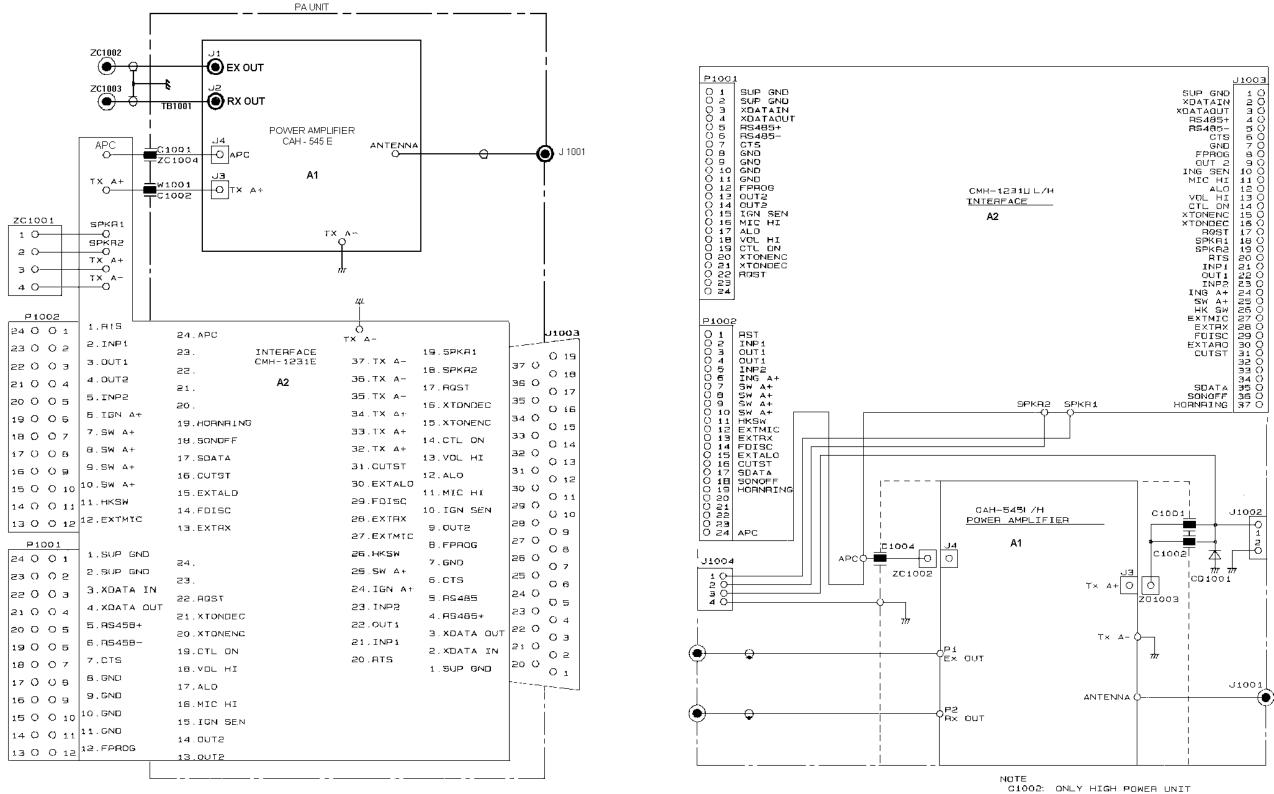
To improve PA stability. Added RC feedback to power amplifier transistor TR1 consisting of a 50-ohm resistor and a 330 pF capacitor.

### REV. A - <u>Power Amplifier Units 344A4573P6 & P7</u> To improve PA stability. Added RC feedback to power amplifier

transistor TR1 consisting of a 50-ohm resistor and a 330 pF capacitor.

## REV. B - Power Amplifier Units 344A4573P1 & P2

For improved ETSI radiated spurs ground clips added.



**INTERCONNECTION DIAGRAM EUROPEAN UHF PA UNIT** 

(DD00-JHM-471PE)

(DD00-JHM-471PL/H)

**U.S.A. UHF PA UNIT** 

**INTERCONNECTION DIAGRAM** 

CD1001: ONLY LOW POWER UNIT

### **COMPONENT IDENTIFICATION CHART 403-512** MHz 35/40-Watt Power Amplifier

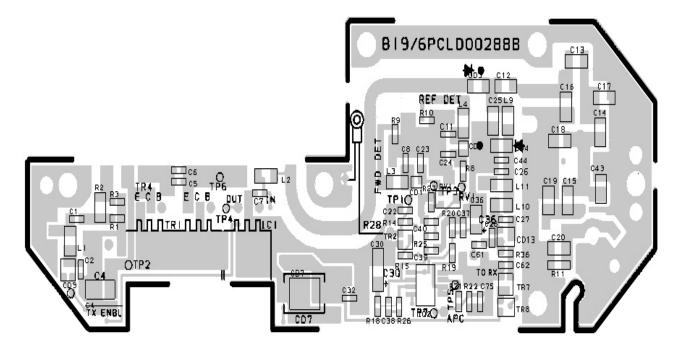
PART	CAH-545LA	CAH-545LB	CAH-545LC
	403-440 MHz (40W)	440-512 MHz (40W)	470-512 MHz (35W)
C7	12 pF	10 pF	10 pF
C9	56 pF	47 pF	47 pF
C10	56 pF	47 pF	36 pF
C11	43 pF	33 pF	39 pF
C12	39 pF	36 pF	36 pF
C13	30 pF	27 pF	22 pF
C41	12 pF	12 pF	10 pF
C50	6 pF	6 pF	5 pF
C58	3 pF	2 pF	$2 \mathrm{pF}$
C59	5 pF	4 pF	3 pF
C60	6 pF	6 pF	7 pF
C61	2 pF	1 pF	$1 \mathrm{pF}$
C64	5 pF	4 pF	3 pF
C65	5 pF	4 pF	4 pF
C66	4 pF	4 pF	3 pF
C67	3pF	-	-
L2	6LALD20855	6LALD20850	6LALD20850
L6	6LALD20855	6LALD20850	6LALD20850

(MADE FROM DD00-CAH-545L 2/2)

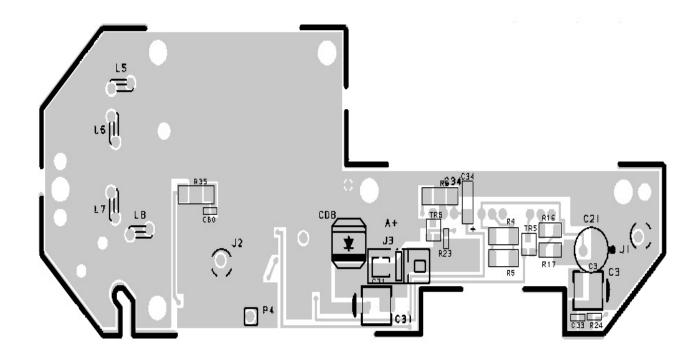
# **COMPONENT IDENTIFICATION CHART 403-512** MHz 80/100-Watt Power Amplifier

PART	САН-545НА	САН-545НВ	CAH-545HC
	403-440 MHz (100W)	440-512 MHz (100W)	470-512 MHz (80W)
C7	12 pF	10 pF	10 pF
C9	56 pF	47 pF	47 pF
C10	56 pF	43 pF	36 pF
C11	43 pF	36 pF	33 pF
C12	43 pF	43 pF	33 pF
C13	30 pF	24 pF	-
C15	5 pF	5 pF	4 pF
C18	10 pF	9 pF	8 pF
C20	56 pF	47 pF	36 pF
C21	47 pF	39 pF	36 pF
C22	43 pF	36 pF	36 pF
C23	43 pF	43 pF	33 pF
C24	30 pF	27 pF	24 pF
C26	10 pF	10 pF	8 pF
C27	10 pF	9 pF	8 pF
C29	47 pF	39 pF	36 pF
C30	56 pF	47 pF	36 pF
C31	43 pF	43 pF	33 pF
C32	43 pF	36 pF	36 pF
C33	30 pF	27 pF	24 pF
C35	10 pF	10 pF	8 pF
C41	6 pF	8 pF	6 pF
C44	6 pF	5 pF	5 pF
C45	6 pF	5  pF	5 pF
C49	8 pF	7 pF	-
C50	-	-	4 pF
C56	3 pF	3 pF	4 pF
C57	7 pF	5 pF	6 pF
C58	3 pF	3 pF	2 pF
C59	3 pF	3 pF	2 pF
C60	3 pF	3  pF	$4 \mathrm{pF}$
C61	2 pF	2 pF	1 pF
C62	7 pF	6 pF	6 pF
C63	4 pF	4 pF	3 pF
C64	3 pF	2 pF	1.5 pF
C65	6 pF	6 pF	4 pF
C66	-	7 pF	5 pF
C97	-	- pi	22 pF
R14	12kΩ	18kΩ	$33k\Omega$
R14 R16	$3.9k\Omega$	3.9kΩ	4.7kΩ
R36	$3.3k\Omega$	$1.8k\Omega$	$1.8k\Omega$
L2	6LALD20855	6LALD20855	6LALD20855
L2 L23	6LALD120833	6LALD120833	6LALD120833
L23 L24	6LALD12014 6LALD12014	6LALD12014	6LALD12013
HC1	M57704M-38	M57704H-38	M57704SH-38

(MADE FROM DD00-CAH-545H 2/2)

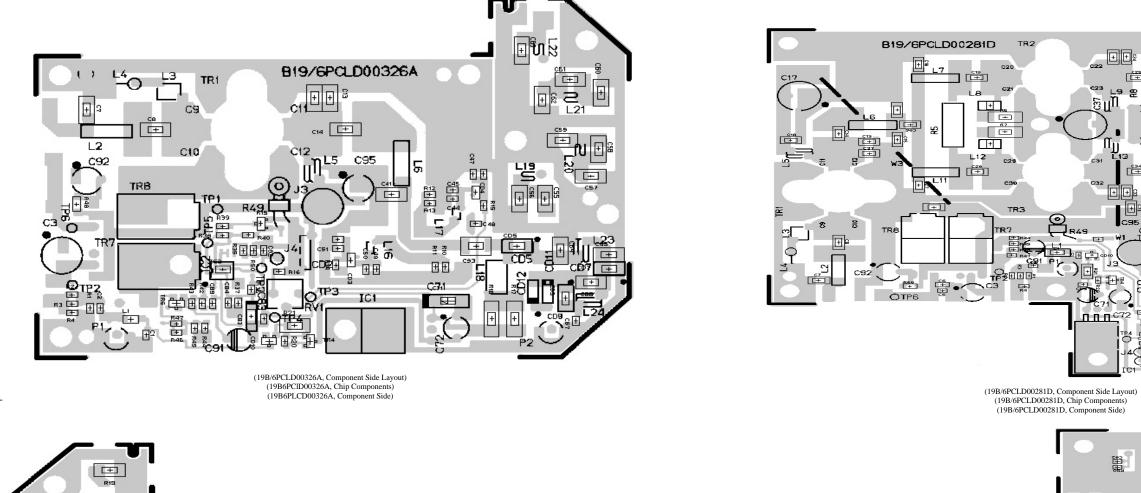


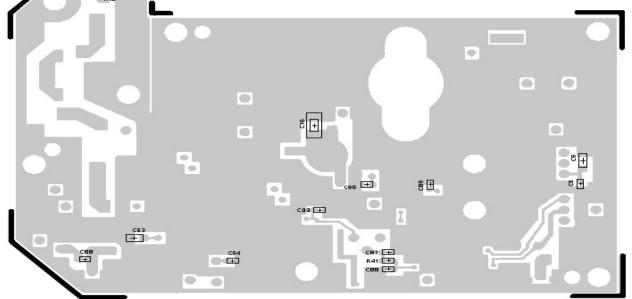
<sup>(</sup>B19/6PCLD00288B, Component Side Layout (B19/6PCLD00288B, Chip Components) (B19/6PClD00288B, Component Side)



(B19/6PCLD00288B, Chip Components) (B19/6PCLD00288B, Solder Side

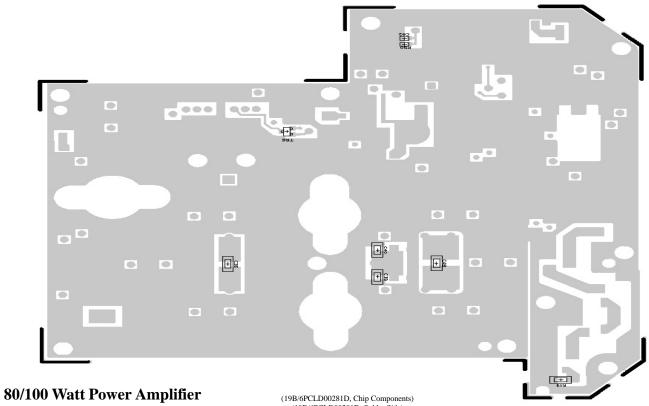
**20-Watt Power Amplifier** CAH-545E





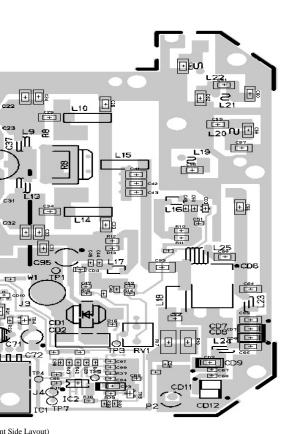
35/40 Watt Power Amplifier CAH-545L

(19B/6PCLD00326A, Component Side Layout) (19B/6PCLD0032A, Chip Components) (19B/6PCLD00326A, Solder Side)



CAH-545H

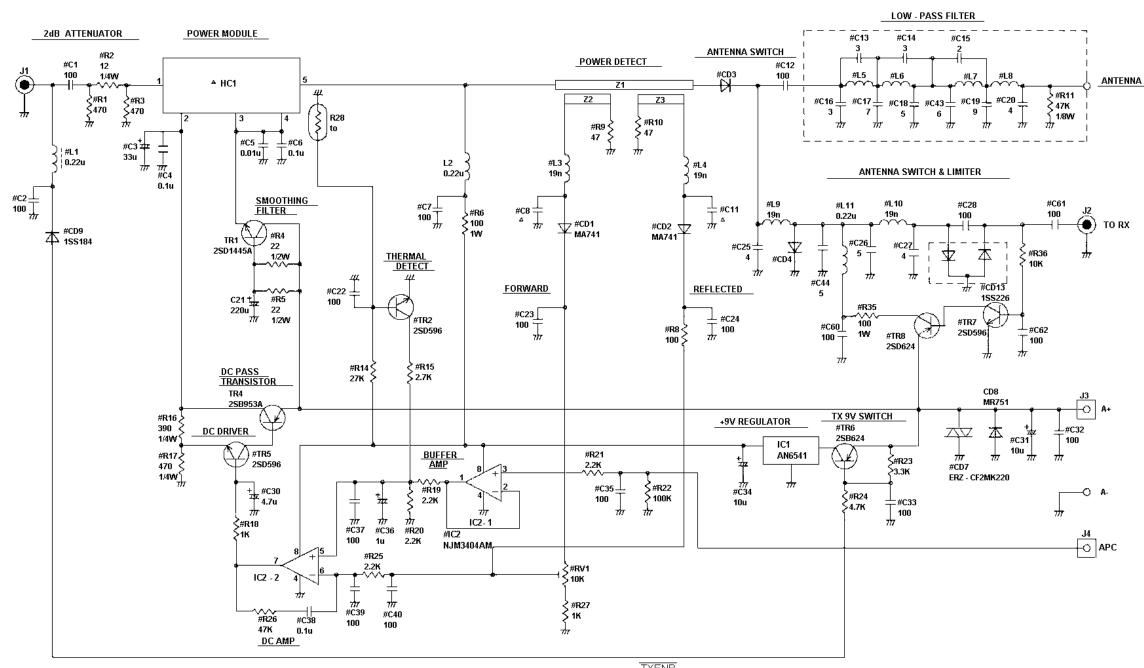
(19B/6PCLD00281D, Chip Components) (19B/6PCLD00281D, Solder Side)



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# SCHEMATIC DIAGRAM



NOTES:

- 1. "#" IDENTIFIES CHIP COMPONENTS
- (EXAMPLE #R12 OR R12#) WHICH ARE LOCATED
- ON THE COMPONENT SIDE OF THE BOARD. 2. Z1, Z2 AND Z3 ARE STRIPLINE PART OF PWB.
- 3. RV1 IS FACTORY TUNED AND DOES NOT REQUIRE FURTHER ADJUSTMENT.

ALL RESISTORS ARE 1/10 OR 1/8 WATT UNLESS OTHERWISE SPECIFIED. RESISTOR VALUES IN  $\Omega$  UNLESS FOLLOWED BY MULTIPLIER K OR M. CAPACITOR VALUES IN P UNLESS FOLLOWED BY MULTIPLIER  $\mu.$ INDUCTANCE VALUES IN H UNLESS FOLLOWED BY MULTIPLIER m OR µ. DC VOLTAGE READINGS

ALL VOLTAGES ARE TYPICAL. VOLTAGES ARE MEASURED WITH A 10Meg OHM PER VOLT METER. REFERENCE TO GROUND. VOLTAGE READINGS ARE TAKEN WITH THE TRANSMITTER UNKEYED/KEYED. EX .45 (UNKEYED)/ .05 (KEYED).

TXENR	
T/LIND	

COMPONENT	IDENTIFICATI

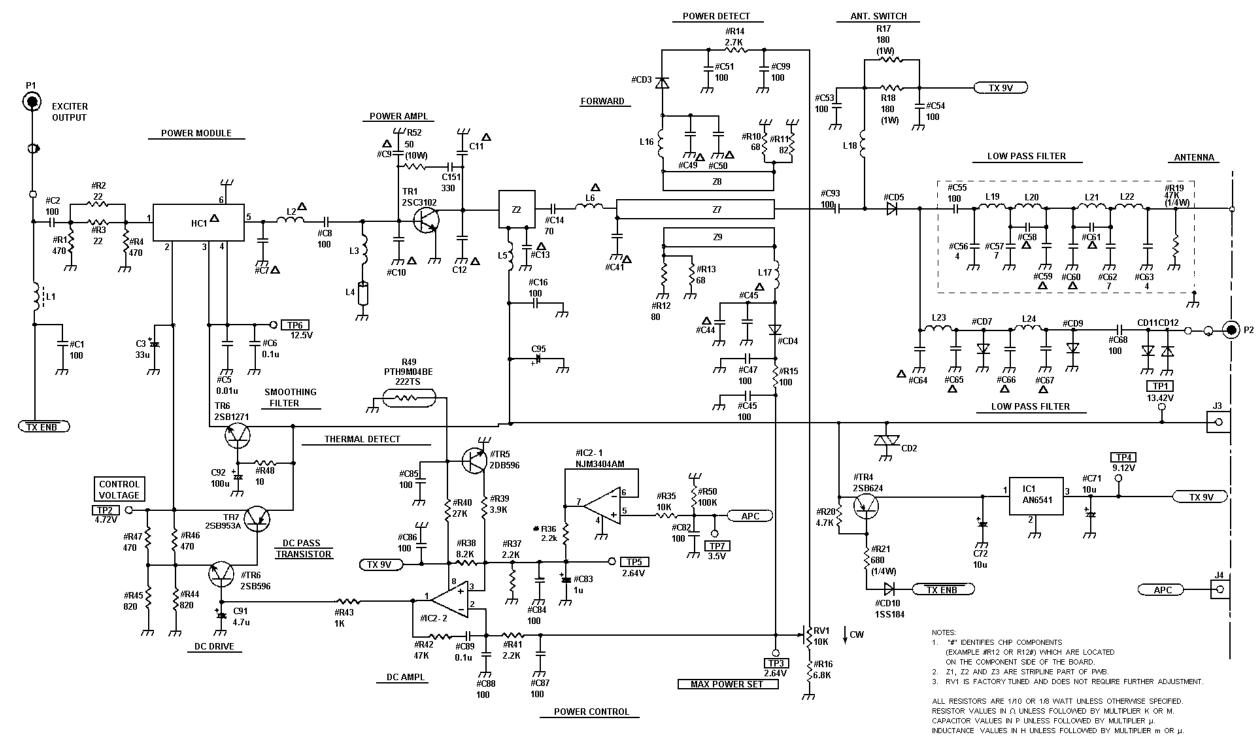
PART SPLIT	378-415 (MHz)	403-440 (MHz)	440 - 470 (MHz)
C8		7pf	6pF
C11		7pF	брF
HC1	M577885L-38	M57788L-38	M57788H-38

# LBI-39034

### ION CHART

# 20 Watt Power Amplifier CAH-545E

(DD00-CAH-545E)

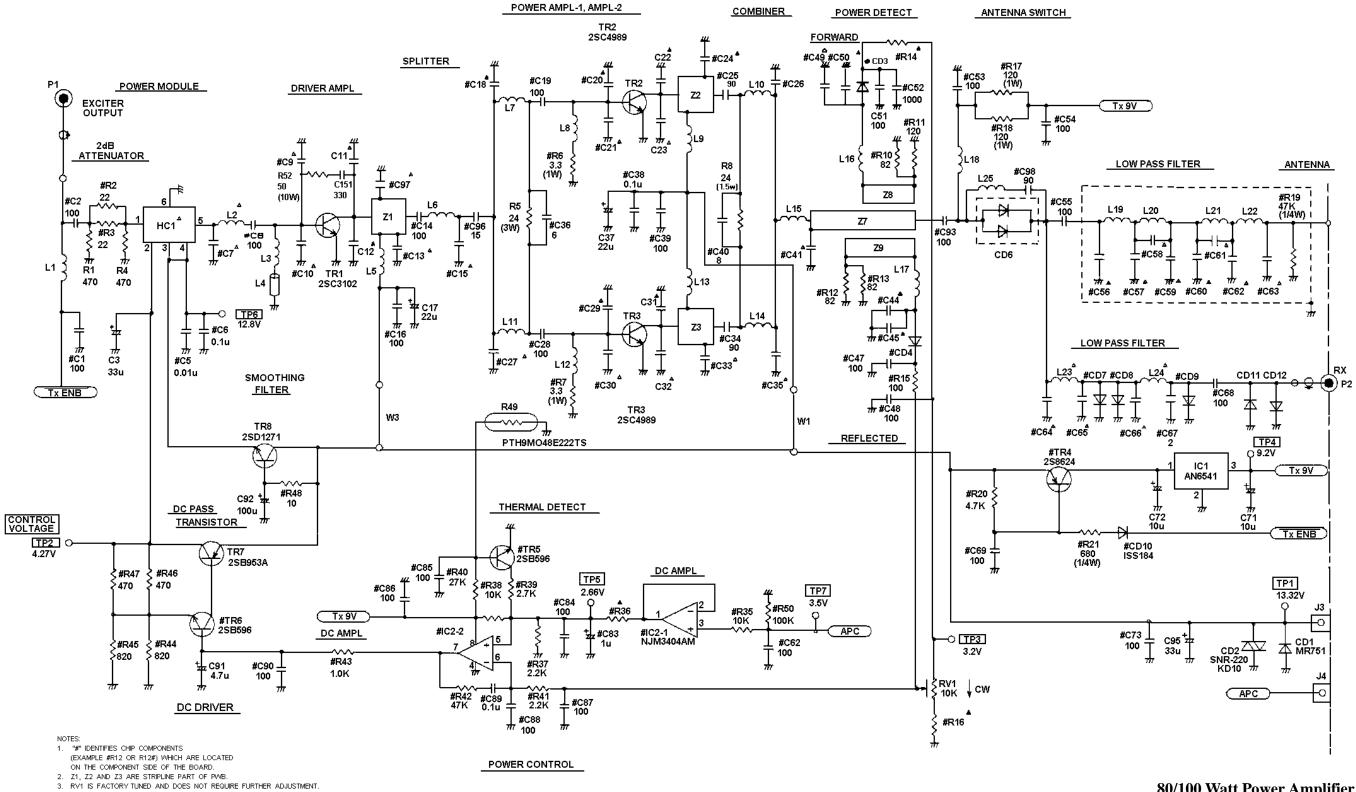


# 35/40 Watt Power Amplifier

CAH-545L

(DD00-CAH-545L 1/2)

### SCHEMATIC DIAGRAM



ALL RESISTORS ARE 1/10 OR 1/8 WATT UNLESS OTHERWISE SPECIFIED. RESISTOR VALUES IN A UNLESS FOLLOWED BY MULTIPLIER K OR M. CAPACITOR VALUES IN P UNLESS FOLLOWED BY MULTIPLIER  $\boldsymbol{\mu}.$ INDUCTANCE. VALUES IN H UNLESS FOLLOWED BY MULTIPLIER m OR  $\mu_{\rm c}$ 

# LBI-39034

# **80/100 Watt Power Amplifier** CAH-545H

(DD00-CAH-545H 1/2)